

Chapter 18

Electrical Specifications and Timings

This chapter contains electrical and timing information for the TMS370 family devices. This information is presented according to device category.

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18.1 Timing Parameter Symbols

Timing parameter symbols occur throughout this chapter. They were created in accordance with JEDEC standard 100A. To keep the symbols short, some of the signal names and other operational terms were abbreviated as follows:

| | | | |
|-----|-------------------------|------|--------------------------|
| A | Address | RXD | SCIRXD |
| AR | Array mode | S | Slave mode |
| B | Byte mode | SC | SYSCLK |
| CI | XTAL2/CLKIN | SCC | SCICLK |
| D | Data | SIMO | SPISIMO |
| E | $\overline{\text{EDS}}$ | SOMI | SPISOMI |
| FE | Final | SPC | SPICLK |
| IE | Initial | TXD | SCITXD |
| M | Master mode | W | Write |
| PGM | Programming | WT | $\overline{\text{WAIT}}$ |
| R | Read | | |

Lowercase subscripts and their meanings are:

| | | | |
|---|---------------------|----|------------------------|
| c | Cycle time (period) | r | Rise time |
| d | Delay time | su | Setup time |
| f | Fall time | v | Valid time |
| h | Hold time | w | Pulse duration (width) |

The following additional letters are used with these meanings:

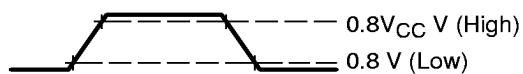
| | | | |
|---|------|---|----------------|
| H | High | V | Valid |
| L | Low | Z | High impedance |

18.2 Parameter Measurements

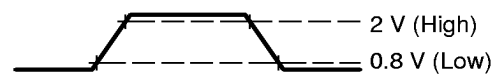
All timings are calculated between high and low measurement points as indicated in Figure 18–1.

Figure 18–1. Measurement Points for Timings

(a) XTAL2/CLKIN measurement points



(b) General measurement points



18.3 Absolute Maximum Ratings for All TMS370 Devices

For all TMS370 devices, Table 18–1 provides the absolute maximum ratings over the operating free-air temperature range. This operating free-air temperature range is specified for your device in its respective section of this chapter.

Stresses beyond those listed in Table 18–1 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the recommended operating conditions for the specific device is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Table 18–1. Absolute Maximum Ratings Over Operating Free-Air Temperature Range (See Note 1)

| Parameter | | Maximum Rating |
|--|--|----------------|
| Supply voltage range, V_{CC} (see Note 1) | | –0.6 V to 7 V |
| Input voltage range | All pins except MC | –0.6 V to 7 V |
| | MC | –0.6 V to 14 V |
| Input clamp current, I_{IK} ($V_I < 0$ V or $V_I > V_{CC}$) | | ± 20 mA |
| Output clamp current, I_{OK} ($V_O < 0$ V or $V_O > V_{CC}$) | | ± 20 mA |
| Continuous output current per buffer, I_O ($V_O = 0$ V to V_{CC}) (see Note 2) | | ± 10 mA |
| Maximum supply current, I_{CC} | | 170 mA |
| Maximum supply current, I_{SS} | | –170 mA |
| Continuous power dissipation | TMS370Cx0xA, TMS370Cx0x, TMS370Cx1xA, TMS370Cx1xB, TMS370CxCA | 500 mW |
| | TMS370Cx32A | 800 mW |
| | TMS370Cx2xA, TMS370Cx2x, TMS370Cx36A, TMS370Cx4xA, TMS370Cx5xA, TMS370Cx5xB, TMS370Cx6xA, TMS370Cx7xA, TMS370Cx8xA, TMS370Cx9xA, TMS370CxAA, TMS370CxBxA | 1 W |
| Storage temperature range, T_{stg} | | –65°C to 150°C |

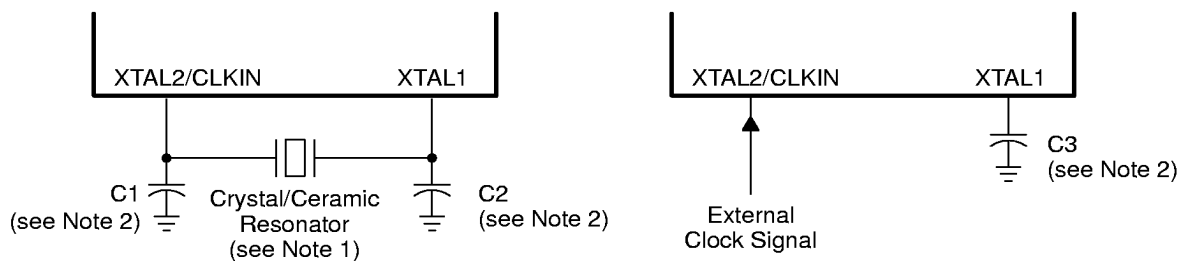
- Notes:**
- 1) Unless otherwise noted, all voltage values are with respect to V_{SS} (ground).
 - 2) Electrical characteristics are specified with all output buffers loaded with the specified I_O . Exceeding the specified I_O in any buffer may affect the levels on other buffers.



18.4 External Crystal/Clock Connections and Typical Circuits for Loads and Buffers

Figure 18–2 illustrates how to connect the crystal/ceramic resonator and the external clock signal. This figure is valid for all TMS370 family devices.

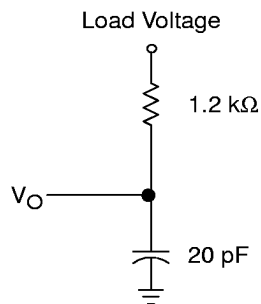
Figure 18–2. Recommended Crystal/Clock Connections



- Notes:**
- 1) The crystal/ceramic resonator frequency is four times the reciprocal of the system clock period.
 - 2) The values of C1 and C2 are typically 15 pF and the value of C3 is typically 50 pF. See the manufacturer's recommendations for ceramic resonators.

Figure 18–3 is an output load circuit that you can use for any TMS370 device.

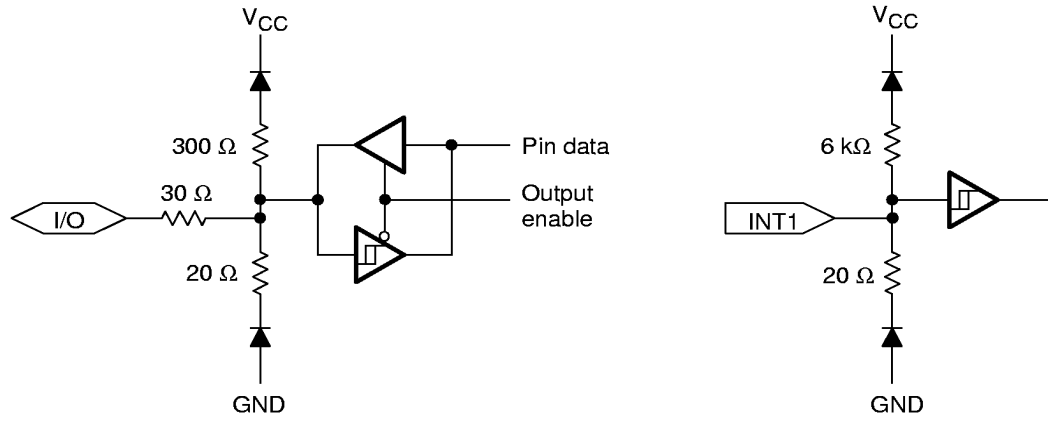
Figure 18–3. Typical Output Load Circuit



- Case 1: $V_O = V_{OH} = 2.4 \text{ V}$; Load Voltage = 0 V
 Case 2: $V_O = V_{OL} = 0.4 \text{ V}$; Load Voltage = 2.1 V

Note: All measurements are made with the pin loading as shown unless otherwise noted. All measurements are made with XTAL2/CLKIN driven by an external square wave signal with a 50% duty cycle and rise and fall times less than 10 ns unless otherwise stated.

Figure 18–4. Typical Buffer Circuitry



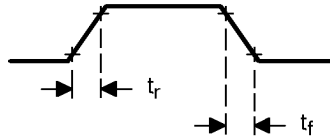
18.5 General-Purpose Output Signal Timings

Refer to Sections 18.1 and 18.2 for timing symbol definitions and parameter measurement points. The timings shown in this section are valid for all TMS370 family devices.

Table 18–2. General-Purpose Output Signal Timing Requirements

| Parameter | | Min | Nom | Max | Unit |
|-----------|-----------|-----|-----|-----|------|
| t_r | Rise time | | 30 | | ns |
| t_f | Fall time | | 30 | | ns |

Figure 18–5. Switching Time Measurement Points



18.6 EPROM/EEPROM Specifications

Refer to Sections 18.1 and 18.2 for timing symbol definitions and parameter measurement points. The timings shown in this section are valid for all 'C702, 'C722, 'CxxxA, and 'CxxxB family devices except the 'C3xxA device.

Table 18–3. EEPROM Timing Requirements for Programming

| Parameter | | Min | Max | Unit |
|----------------|--|-----|-----|------|
| $t_{w(PGM)B}$ | Pulse duration, programming signal to ensure valid data is stored (byte mode) | 10 | | ms |
| $t_{w(PGM)AR}$ | Pulse duration, programming signal to ensure valid data is stored (array mode) | 20 | | ms |

Table 18–4. Recommended EPROM Operating Conditions for Programming

| Parameter | | Min | Nom | Max | Unit |
|-----------|--|-------------------|------|------|------|
| V_{CC} | Supply voltage | 4.75 | 5.5 | 6 | V |
| V_{PP} | Supply voltage at MC pin | 13 | 13.2 | 13.5 | V |
| I_{PP} | Supply current at MC pin during programming ($V_{PP} = 13\text{ V}$) | | 30 | 50 | mA |
| SYSCLK | System clock operating frequency | Divide-by-4 clock | 0.5 | 5 | MHz |
| | | Divide-by-1 clock | 2 | 5 | MHz |

Table 18–5. EPROM Timing Requirements for Programming

| Parameter | | Min | Nom | Max | Unit |
|---------------|---|------|------|-----|------|
| $t_{w(EPGM)}$ | Pulse duration, programming signal (see Note) | 0.40 | 0.50 | 3 | ms |

Note: Programming pulse is active when both EXE (EPCTL.0) and VPPS (EPCTL.6) are set.

Note:

The parameters V_{PP} and $t_{w(EPGM)}$ for EPROM are different for the TMS370Cxxx devices (vs. the TMS370CxxxA or TMS370CxxxB devices). Refer to subsection A.9.3, *Differences in EPROM Specifications*, on page A-10.



18.7 TMS370Cx0xA and TMS370Cx0x Specifications

The tables in this section give specifications that apply to the devices in the TMS370Cx0xA and TMS370Cx0x categories. These devices include the TMS370C002A, TMS370C302A, TMS370C702, and SE370C702.

18.7.1 TMS370Cx0xA and TMS370Cx0x Electrical Specifications

Stresses beyond those listed in Table 18–1 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the recommended operating conditions in Table 18–6 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Table 18–6. Recommended Operating Conditions (See Note 1)

| Parameter | | Min | Nom | Max | Unit | |
|-----------------|--|--|--------------------|-----------------|------|---|
| V _{CC} | Supply voltage (see Note 1) | 4.5 | 5 | 5.5 | V | |
| | RAM data-retention supply voltage (see Note 2) | 3 | | 5.5 | V | |
| V _{IL} | Low-level input voltage | All pins except MC | V _{SS} | 0.8 | V | |
| | | MC, normal operation | V _{SS} | 0.3 | V | |
| V _{IH} | High-level input voltage | All pins except MC, XTAL2/CLKIN, and RESET | 2 | V _{CC} | V | |
| | | XTAL2/CLKIN | 0.8V _{CC} | V _{CC} | V | |
| | | RESET | 0.7V _{CC} | V _{CC} | V | |
| V _{MC} | MC (mode control) voltage | EEPROM write-protect override (WPO) mode | 11.7 | 12 | 13 | V |
| | | EPROM programming voltage (V _{PP}) | 13 | 13.2 | 13.5 | V |
| | | Microcomputer mode | V _{SS} | | 0.3 | V |
| T _A | Operating free-air temperature | L version | 0 | 70 | °C | |
| | | A version | –40 | 85 | °C | |
| | | T version | –40 | 105 | °C | |

- Notes:**
- 1) Unless otherwise noted, all voltage values are with respect to V_{SS} (ground).
 - 2) RESET must be activated externally when V_{CC} or SYSCLK is out of the recommended operating range.



Table 18–7. Electrical Characteristics Over Recommended Operating Free-Air Temperature Range

| Parameter | | Test Conditions | Min | Typ | Max | Unit | |
|-----------|---|---------------------------------------|---|-----|----------|---------------|---------------|
| V_{OL} | Low-level output voltage | $I_{OL} = 1.4 \text{ mA}$ | | | 0.4 | V | |
| V_{OH} | High-level output voltage | $I_{OH} = -50 \mu\text{A}$ | $0.9V_{CC}$ | | | V | |
| | | $I_{OH} = -2 \text{ mA}$ | 2.4 | | | V | |
| I_I | Input current | MC | $0 \text{ V} \leq V_I \leq 0.3 \text{ V}$ | | | 10 | μA |
| | | | $0.3 \text{ V} < V_I \leq 13 \text{ V}$ | | | 650 | μA |
| | | | $12 \text{ V} \leq V_I \leq 13 \text{ V}$ (see Note 1) | | | 50 | mA |
| | I/O pins | $0 \text{ V} \leq V_I \leq V_{CC}$ | | | ± 10 | μA | |
| I_{OL} | Low-level output current | $V_{OL} = 0.4 \text{ V}$ | 1.4 | | | mA | |
| I_{OH} | High-level output current | $V_{OH} = 0.9V_{CC}$ | -50 | | | μA | |
| | | $V_{OH} = 2.4 \text{ V}$ | -2 | | | mA | |
| I_{CC} | Supply current (operating mode) OSC POWER bit = 0 (see Note 4) | See Notes 2 and 3 SYSCLK = 5 MHz | | 20 | 36 | mA | |
| | | See Notes 2 and 3 SYSCLK = 3 MHz | | 13 | 25 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 5 | 11 | mA | |
| I_{CC} | Supply current (STANDBY mode) OSC POWER bit = 0 (see Note 5) | See Notes 2 and 3 SYSCLK = 5 MHz | | 10 | 17 | mA | |
| | | See Notes 2 and 3 SYSCLK = 3 MHz | | 6.5 | 11 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 2 | 3.5 | mA | |
| I_{CC} | Supply current (STANDBY mode) OSC POWER bit = 1 (see Note 6) | See Notes 2 and 3 SYSCLK = 3 MHz | | 4.5 | 8.6 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 1.5 | 3.0 | mA | |
| I_{CC} | Supply current (HALT mode) | See Note 2 XTAL2/CLKIN < 0.2 V | | 1 | 30 | μA | |

- Notes:**
- 1) Input current I_{pp} is a maximum of 50 mA only when EPROM is being programmed.
 - 2) Single-chip mode, ports configured as inputs or as outputs with no load. All inputs $\leq 0.2 \text{ V}$ or $\geq V_{CC} - 0.2 \text{ V}$.
 - 3) XTAL2/CLKIN is driven with an external square wave signal with 50% duty cycle and rise and fall times less than 10 ns. Current can be higher with a crystal oscillator. At 5-MHz SYSCLK, this extra current = $0.01 \text{ mA} \times (\text{total load capacitance} + \text{crystal capacitance in pF})$.
 - 4) Maximum operating current = $5.6 (\text{SYSCLK}) + 8 \text{ mA}$.
 - 5) Maximum standby current = $3 (\text{SYSCLK}) + 2 \text{ mA}$ (OSC POWER bit = 0).
 - 6) Maximum standby current = $2.24 (\text{SYSCLK}) + 1.9 \text{ mA}$ (OSC POWER bit = 1, only valid up to 3 MHz of SYSCLK).

18.7.2 TMS370Cx0xA and TMS370Cx0x Timings

Refer to Sections 18.1 and 18.2 (both on page 18-2) for timing symbol definitions and parameter measurement points.

Table 18–8. External Clocking Requirements for Divide-by-4 Clock (See Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|--|-----|-----|------|
| 1 | $t_{w(CI)}$ Pulse duration, XTAL2/CLKIN (see Note 2) | 20 | | ns |
| 2 | $t_{r(CI)}$ Rise time, XTAL2/CLKIN | | 30 | ns |
| 3 | $t_{f(CI)}$ Fall time, XTAL2/CLKIN | | 30 | ns |
| 4 | $t_{d(CIH-SCL)}$ Delay time, XTAL2/CLKIN rise to SYSCLK fall | | 100 | ns |
| | CLKIN | 2 | 20 | MHz |
| | SYSCLK | 0.5 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–6.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–6, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle, or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/4$

Figure 18–6. External Clock Timing for Divide-by-4 Clock

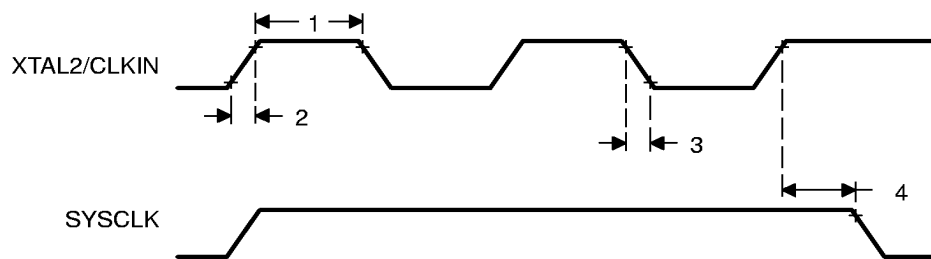


Table 18–9. External Clocking Requirements for Divide-by-1 Clock (PLL) (see Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|------------------|-----|-----|------|
| 1 | $t_{w(CI)}$ | 20 | | ns |
| 2 | $t_{r(CI)}$ | | 30 | ns |
| 3 | $t_{f(CI)}$ | | 30 | ns |
| 4 | $t_{d(CIH-SCH)}$ | | 100 | ns |
| | CLKIN | 2 | 5 | MHz |
| | SYSCLOCK | 2 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–6.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–7, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle, or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLOCK = CLKIN/1$

Figure 18–7. External Clock Timing for Divide-by-1 Clock

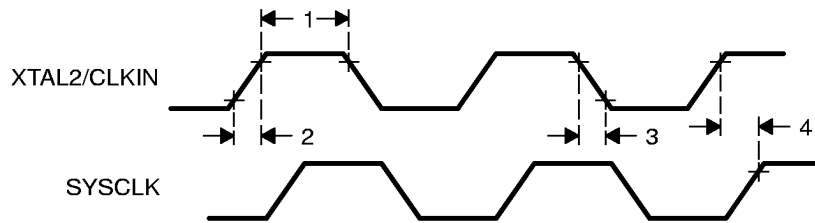
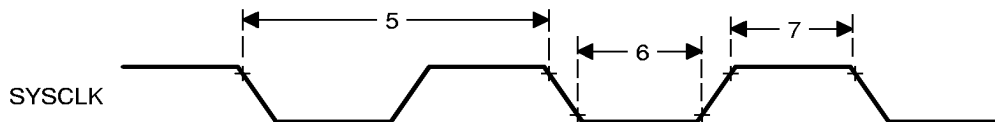


Table 18–10. Switching Characteristics and Timing Requirements (See Note)

| No. | Parameter | Min | Max | Unit | |
|-----|--------------|----------------------|---------------|------|----|
| 5 | t_c | Cycle time, SYSCLOCK | 200 | 2000 | ns |
| | | | 200 | 500 | ns |
| 6 | $t_{w(SCL)}$ | $0.5t_c - 20$ | $0.5t_c$ | ns | |
| 7 | $t_{w(SCH)}$ | $0.5t_c$ | $0.5t_c + 20$ | ns | |

Note: $t_c =$ system clock cycle time = $1 / SYSCLOCK$

Figure 18–8. SYSCLOCK Timing



18.8 TMS370Cx1xA and TMS370Cx1xB Specifications

The tables in this section give specifications that apply to the devices in the TMS370Cx1xA and the TMS370Cx1xB categories. These devices include the TMS370C010A, TMS370C012A, TMS370C310A, TMS370C311A, TMS370C312A, TMS370C712A, TMS370C712B, SE370C712A, and SE370C712B.

18.8.1 TMS370Cx1xA and TMS370Cx1xB Electrical Specifications

Stresses beyond those listed in Table 18–1 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the recommended operating conditions in Table 18–11 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Table 18–11. Recommended Operating Conditions (See Note 1)

| Parameter | | Min | Nom | Max | Unit | |
|-----------------|--|--|--------------------|-----------------|------|---|
| V _{CC} | Supply voltage (see Note 1) | 4.5 | 5 | 5.5 | V | |
| | RAM data-retention supply voltage (see Note 2) | 3 | | 5.5 | V | |
| V _{IL} | Low-level input voltage | All pins except MC | V _{SS} | 0.8 | V | |
| | | MC, normal operation | V _{SS} | 0.3 | V | |
| V _{IH} | High-level input voltage | All pins except MC, XTAL2/CLKIN, and $\overline{\text{RESET}}$ | 2 | V _{CC} | V | |
| | | XTAL2/CLKIN | 0.8V _{CC} | V _{CC} | V | |
| | | $\overline{\text{RESET}}$ | 0.7V _{CC} | V _{CC} | V | |
| V _{MC} | MC (mode control) voltage | EEPROM write-protect override (WPO) mode | 11.7 | 12 | 13 | V |
| | | EPROM programming voltage (V _{PP}) | 13 | 13.2 | 13.5 | V |
| | | Microcomputer mode | V _{SS} | | 0.3 | V |
| T _A | Operating free-air temperature | L version | 0 | 70 | °C | |
| | | A version | –40 | 85 | °C | |
| | | T version | –40 | 105 | °C | |

- Notes:**
- 1) Unless otherwise noted, all voltage values are with respect to V_{SS} (ground).
 - 2) $\overline{\text{RESET}}$ must be externally activated when V_{CC} or SYSCLK is not within the recommended operating range.



Table 18–12. Electrical Characteristics Over Recommended Operating Free-Air Temperature Range

| Parameter | | Test Conditions | Min | Typ | Max | Unit | |
|-----------|---|---------------------------------------|---|-----|----------|---------------|---------------|
| V_{OL} | Low-level output voltage | $I_{OL} = 1.4 \text{ mA}$ | | | 0.4 | V | |
| V_{OH} | High-level output voltage | $I_{OH} = -50 \mu\text{A}$ | $0.9V_{CC}$ | | | V | |
| | | $I_{OH} = -2 \text{ mA}$ | 2.4 | | | V | |
| I_I | Input current | MC | $0 \text{ V} \leq V_I \leq 0.3 \text{ V}$ | | | 10 | μA |
| | | | $0.3 \text{ V} < V_I \leq 13 \text{ V}$ | | | 650 | μA |
| | | | $12 \text{ V} \leq V_I \leq 13 \text{ V}$ (see Note 1) | | | 50 | mA |
| | I/O pins | $0 \text{ V} \leq V_I \leq V_{CC}$ | | | ± 10 | μA | |
| I_{OL} | Low-level output current | $V_{OL} = 0.4 \text{ V}$ | 1.4 | | | mA | |
| I_{OH} | High-level output current | $V_{OH} = 0.9V_{CC}$ | -50 | | | μA | |
| | | $V_{OH} = 2.4 \text{ V}$ | -2 | | | mA | |
| I_{CC} | Supply current (operating mode) OSC POWER bit = 0 (see Note 4) | See Notes 2 and 3 SYSCLK = 5 MHz | | 20 | 36 | mA | |
| | | See Notes 2 and 3 SYSCLK = 3 MHz | | 13 | 25 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 5 | 11 | mA | |
| I_{CC} | Supply current (STANDBY mode) OSC POWER bit = 0 (see Note 5) | See Notes 2 and 3 SYSCLK = 5 MHz | | 10 | 17 | mA | |
| | | See Notes 2 and 3 SYSCLK = 3 MHz | | 6.5 | 11 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 2 | 3.5 | mA | |
| I_{CC} | Supply current (STANDBY mode) OSC POWER bit = 1 (see Note 6) | See Notes 2 and 3 SYSCLK = 3 MHz | | 4.5 | 8.6 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 1.5 | 3.0 | mA | |
| I_{CC} | Supply current (HALT mode) | See Note 2 XTAL2/CLKIN < 0.2 V | | 1 | 30 | μA | |

- Notes:**
- 1) Input current I_{pp} is a maximum of 50 mA only when EPROM is being programmed.
 - 2) Single-chip mode, ports configured as inputs or as outputs with no load. All inputs $\leq 0.2 \text{ V}$ or $\geq V_{CC} - 0.2 \text{ V}$.
 - 3) XTAL2/CLKIN is driven with an external square wave signal with 50% duty cycle and rise and fall times less than 10 ns. Current can be higher with a crystal oscillator. At 5-MHz SYSCLK, this extra current = $0.01 \text{ mA} \times (\text{total load capacitance} + \text{crystal capacitance in pF})$.
 - 4) Maximum operating current = $5.6(\text{SYSCLK}) + 8 \text{ mA}$.
 - 5) Maximum standby current = $3(\text{SYSCLK}) + 2 \text{ mA}$ (OSC POWER bit = 0).
 - 6) Maximum standby current = $2.24(\text{SYSCLK}) + 1.9 \text{ mA}$ (OSC POWER bit = 1; valid only up to 3-MHz SYSCLK).

18.8.2 TMS370Cx1xA and TMS370Cx1xB Timings

Refer to Sections 18.1 and 18.2 (both on page 18-2) for timing symbol definitions and parameter measurement points.

Table 18–13. External Clocking Requirements for Divide-by-4 Clock (See Note 1)

| No. | Parameter | Min | Max | Unit | |
|-----|--|--|-----|------|-----|
| 1 | $t_{w(CI)}$ Pulse duration, XTAL2/CLKIN (see Note 2) | 20 | | ns | |
| 2 | $t_{r(CI)}$ Rise time, XTAL2/CLKIN | | 30 | ns | |
| 3 | $t_{f(CI)}$ Fall time, XTAL2/CLKIN | | 30 | ns | |
| 4 | $t_{d(CIH-SCL)}$ Delay time, XTAL2/CLKIN rise to SYSCLK fall | | 100 | ns | |
| | CLKIN | Crystal operating frequency | 2 | 20 | MHz |
| | SYSCLK | Internal system clock operating frequency (see Note 3) | 0.5 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–11.
 - 2) This pulse may be either a high pulse, as illustrated in Figure 18–9, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/4$

Figure 18–9. External Clock Timing for Divide-by-4 Clock

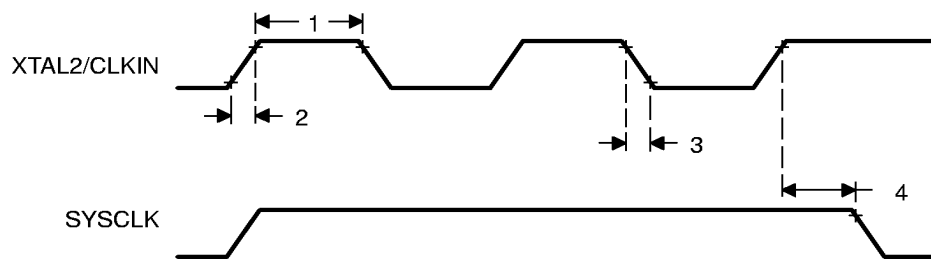


Table 18–14. External Clocking Requirements for Divide-by-1 Clock (PLL) (see Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|------------------|-----|-----|------|
| 1 | $t_{w(CI)}$ | 20 | | ns |
| 2 | $t_{r(CI)}$ | | 30 | ns |
| 3 | $t_{f(CI)}$ | | 30 | ns |
| 4 | $t_{d(CIH-SCH)}$ | | 100 | ns |
| | CLKIN | 2 | 5 | MHz |
| | SYSCCLK | 2 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–11.
 - 2) This pulse may be either a high pulse, as illustrated in Figure 18–10, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCCLK = CLKIN/1$

Figure 18–10. External Clock Timing for Divide-by-1 Clock

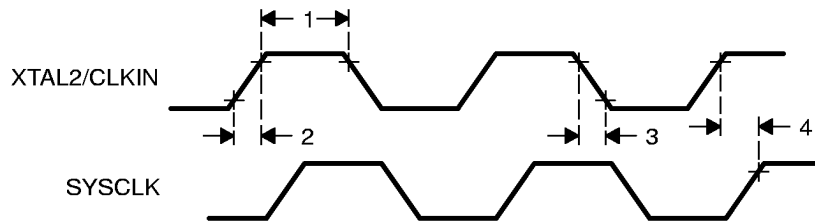
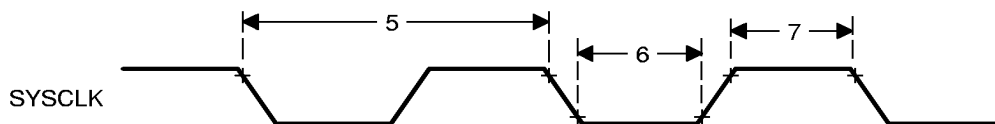


Table 18–15. Switching Characteristics and Timing Requirements (see Note)

| No. | Parameter | Min | Max | Unit | |
|-----|--------------|---------------------|---------------|------|----|
| 5 | t_c | Cycle time, SYSCCLK | 200 | 2000 | ns |
| | | | 200 | 500 | ns |
| 6 | $t_{w(SCL)}$ | $0.5t_c - 20$ | $0.5t_c$ | ns | |
| 7 | $t_{w(SCH)}$ | $0.5t_c$ | $0.5t_c + 20$ | ns | |

Note: $t_c =$ system clock cycle time = $1 / SYSCCLK$

Figure 18–11. SYSCCLK Timing



18.9 TMS370Cx2xA and TMS370Cx2x Specifications

The tables in this section give specifications that apply to the devices in the TMS370Cx2xA TMS370Cx2x categories. These devices include the TMS370C020A, TMS370C022A, TMS370C320A, TMS370C322A, TMS370C722, and SE370C722.

18.9.1 TMS370Cx2xA and TMS370Cx2x Electrical Specifications

Stresses beyond those listed in Table 18–1 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the recommended operating conditions in Table 18–16 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Table 18–16. Recommended Operating Conditions (See Note 1)

| Parameter | | Min | Nom | Max | Unit | |
|-----------------|--|--|--------------------|-----------------|------|---|
| V _{CC} | Supply voltage | 4.5 | 5 | 5.5 | V | |
| | RAM data-retention supply voltage (see Note 2) | 3 | | 5.5 | V | |
| V _{IL} | Low-level input voltage | All pins except MC | | 0.8 | V | |
| | | MC, normal operation | V _{SS} | 0.3 | V | |
| V _{IH} | High-level input voltage | All pins except MC, XTAL2/CLKIN, and RESET | 2 | V _{CC} | V | |
| | | XTAL2/CLKIN | 0.8V _{CC} | V _{CC} | V | |
| | | RESET | 0.7V _{CC} | V _{CC} | V | |
| V _{MC} | MC (mode control) voltage | EEPROM write-protect override (WPO) mode | 11.7 | 12 | 13 | V |
| | | EPROM programming voltage (V _{PP}) | 13 | 13.2 | 13.5 | V |
| | | Microcomputer mode | V _{SS} | | 0.3 | V |
| T _A | Operating free-air temperature | L version | 0 | 70 | °C | |
| | | A version | –40 | 85 | °C | |
| | | T version | –40 | 105 | °C | |

- Notes:**
- 1) Unless otherwise noted, all voltages are with respect to V_{SS} (ground).
 - 2) RESET must be externally activated when V_{CC} or SYSCLK is out of the recommended operating range.



Table 18–17. Electrical Characteristics Over Recommended Operating Free-Air Temperature Range

| Parameter | | Test Conditions | Min | Typ | Max | Unit |
|-----------|---|---------------------------------------|---|-----|----------|-------------------|
| V_{OL} | Low-level output voltage | $I_{OL} = 1.4 \text{ mA}$ | | | 0.4 | V |
| V_{OH} | High-level output voltage | $I_{OH} = -50 \mu\text{A}$ | $0.9V_{CC}$ | | | V |
| | | $I_{OH} = -2 \text{ mA}$ | 2.4 | | | V |
| I_I | Input current | MC | $0 \text{ V} < V_I \leq 0.3 \text{ V}$ | | | 10 μA |
| | | | $0.3 \text{ V} < V_I \leq 13 \text{ V}$ | | | 650 μA |
| | | | $12 \text{ V} \leq V_I \leq 13 \text{ V}$ (see Note 1) | | | 50 mA |
| | I/O pins | $0 \text{ V} \leq V_I \leq V_{CC}$ | | | ± 10 | μA |
| I_{OL} | Low-level output current | $V_{OL} = 0.4 \text{ V}$ | 1.4 | | | mA |
| I_{OH} | High-level output current | $V_{OH} = 0.9V_{CC}$ | -50 | | | μA |
| | | $V_{OH} = 2.4 \text{ V}$ | -2 | | | mA |
| I_{CC} | Supply current (operating mode) OSC POWER bit = 0 (see Note 4) | See Notes 2 and 3 SYSCLK = 5 MHz | | 30 | 45 | mA |
| | | See Notes 2 and 3 SYSCLK = 3 MHz | | 20 | 30 | mA |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 7 | 11 | mA |
| I_{CC} | Supply current (STANDBY mode) OSC POWER bit = 0 (see Note 5) | See Notes 2 and 3 SYSCLK = 5 MHz | | 10 | 17 | mA |
| | | See Notes 2 and 3 SYSCLK = 3 MHz | | 8 | 11 | mA |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 2 | 3.5 | mA |
| I_{CC} | Supply current (STANDBY mode) OSC POWER bit = 1 (see Note 6) | See Notes 2 and 3 SYSCLK = 3 MHz | | 6 | 8.6 | mA |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 2 | 3.0 | mA |
| I_{CC} | Supply current (HALT mode) | See Note 2 XTAL2/CLKIN < 0.2 V | | 2 | 30 | μA |

- Notes:**
- 1) Input current I_{pp} is a maximum of 50 mA only when EPROM is being programmed.
 - 2) Single-chip mode, ports configured as inputs or as outputs with no load. All inputs $\leq 0.2 \text{ V}$ or $\geq V_{CC} - 0.2 \text{ V}$.
 - 3) XTAL2/CLKIN is driven with an external square wave signal with 50% duty cycle and rise and fall times less than 10 ns. Current can be higher with a crystal oscillator. At 5-MHz SYSCLK, this extra current = $0.01 \text{ mA} \times (\text{total load capacitance} + \text{crystal capacitance in pF})$.
 - 4) Maximum operating current = $7.6(\text{SYSCLK}) + 7 \text{ mA}$.
 - 5) Maximum standby current = $3(\text{SYSCLK}) + 2 \text{ mA}$ (OSC POWER bit = 0).
 - 6) Maximum standby current = $2.24(\text{SYSCLK}) + 1.9 \text{ mA}$ (OSC POWER bit = 1; valid only up to 3-MHz SYSCLK).

18.9.2 TMS370Cx2xA and TMS370Cx2x Timings

Refer to Sections 18.1 and 18.2 (both on page 18-2) for timing symbol definitions and parameter measurement points.

Table 18–18. External Clocking Requirements for Divide-by-4 Clock (See Note 1)

| No. | Parameter | Min | Max | Unit | |
|-----|--|--|-----|------|-----|
| 1 | $t_{w(CI)}$ Pulse duration, XTAL2/CLKIN (see Note 2) | 20 | | ns | |
| 2 | $t_{r(CI)}$ Rise time, XTAL2/CLKIN | | 30 | ns | |
| 3 | $t_{f(CI)}$ Fall time, XTAL2/CLKIN | | 30 | ns | |
| 4 | $t_{d(CIH-SCL)}$ Delay time, XTAL2/CLKIN rise to SYSCLK fall | | 100 | ns | |
| | CLKIN | Crystal operating frequency | 2 | 20 | MHz |
| | SYSCLK | Internal system clock operating frequency (see Note 3) | 0.5 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–16.
 - 2) This pulse may be either a high pulse, as illustrated in Figure 18–12, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle, or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/4$

Figure 18–12. External Clock Timing for Divide-by-4 Clock

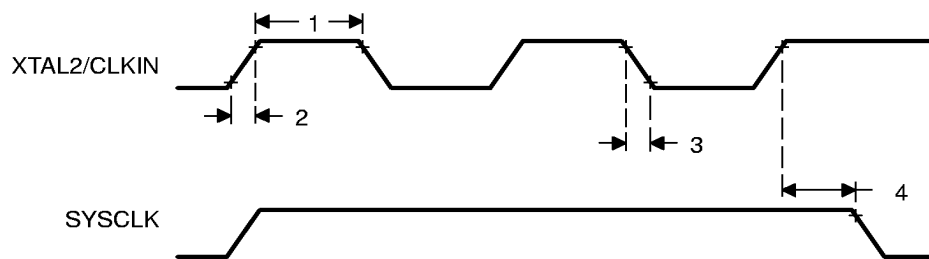


Table 18–19. External Clocking Requirements for Divide-by-1 Clock (PLL) (See Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|---|-----|-----|------|
| 1 | $t_{w(CI)}$ Pulse duration, XTAL2/CLKIN (see Note 2) | 20 | | ns |
| 2 | $t_{r(CI)}$ Rise time, XTAL2/CLKIN | | 30 | ns |
| 3 | $t_{f(CI)}$ Fall time, XTAL2/CLKIN | | 30 | ns |
| 4 | $t_{d(CIH-SCH)}$ Delay time, XTAL2/CLKIN rise to SYSCLK rise | | 100 | ns |
| | CLKIN Crystal operating frequency | 2 | 5 | MHz |
| | SYSCLK Internal system clock operating frequency (see Note 3) | 2 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–16.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–13, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle, or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/1$

Figure 18–13. External Clock Timing for Divide-by-1 Clock

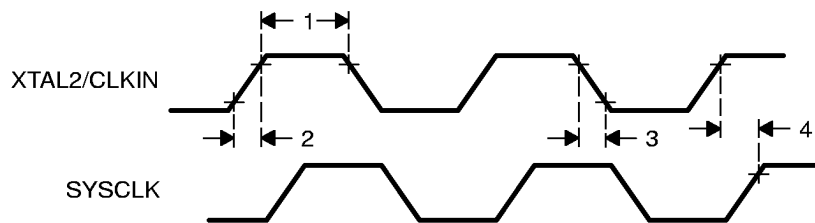
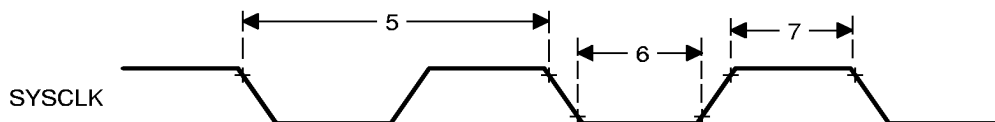


Table 18–20. Switching Characteristics and Timing Requirements (See Note)

| No. | Parameter | Min | Max | Unit | |
|-----|--|-------------------|---------------|------|----|
| 5 | t_c Cycle time, SYSCLK | Divide-by-4 clock | 200 | 2000 | ns |
| | | Divide-by-1 clock | 200 | 500 | |
| 6 | $t_{w(SCL)}$ Pulse duration, SYSCLK low | $0.5t_c - 20$ | $0.5t_c$ | ns | |
| 7 | $t_{w(SCH)}$ Pulse duration, SYSCLK high | $0.5t_c$ | $0.5t_c + 20$ | ns | |

Note: $t_c = \text{system-clock cycle time} = 1/\text{SYSCLK}$

Figure 18–14. SYSCLK Timing



18.10 TMS370Cx32A Specifications

The tables in this section give specifications that apply to the devices in the TMS370Cx32A category. These devices include the TMS370C032A, TMS370C332A, TMS370C732A, and SE370C732A.

18.10.1 TMS370Cx32A Electrical Specifications

Stresses beyond those listed in Table 18–1 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the recommended operating conditions in Table 18–21 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Table 18–21. Recommended Operating Conditions (See Note 1)

| Parameter | | Min | Nom | Max | Unit | |
|------------------|--|--|---------------------|------------------|------|---|
| V _{CC1} | Supply voltage | 4.5 | 5 | 5.5 | V | |
| | RAM data-retention supply voltage (see Note 2) | 3 | | 5.5 | V | |
| V _{CC3} | Analog supply voltage | 4.5 | 5 | 5.5 | V | |
| V _{SS3} | Analog supply ground | –0.3 | 0 | 0.3 | V | |
| V _{IL} | Low-level input voltage | All pins except MC | V _{SS1} | 0.8 | V | |
| | | MC, normal operation | V _{SS1} | 0.3 | V | |
| V _{IH} | High-level input voltage | All pins except MC, XTAL2/CLKIN, and $\overline{\text{RESET}}$ | 2 | V _{CC1} | V | |
| | | XTAL2/CLKIN | 0.8V _{CC1} | V _{CC1} | V | |
| | | $\overline{\text{RESET}}$ | 0.7V _{CC1} | V _{CC1} | V | |
| V _{MC} | MC (mode control) voltage | EEPROM write-protect override (WPO) mode | 11.7 | 12 | 13 | V |
| | | EPROM programming voltage (V _{PP}) | 13 | 13.2 | 13.5 | V |
| | | Microcomputer mode | V _{SS1} | | 0.3 | V |
| T _A | Operating free-air temperature | L version | 0 | 70 | °C | |
| | | A version | –40 | 85 | °C | |
| | | T version | –40 | 105 | °C | |

- Notes:**
- 1) Unless otherwise noted, all voltage values are with respect to V_{SS1}.
 - 2) $\overline{\text{RESET}}$ must be externally activated when V_{CC1} or SYSCLK is not within the recommended operating range.



Table 18–22. Electrical Characteristics Over Recommended Operating Free-Air Temperature Range

| Parameter | | Test Conditions | Min | Typ | Max | Unit | |
|------------------|--|---|--|-----|------|------|----|
| V _{OL} | Low-level output voltage | I _{OL} = 1.4 mA | | | 0.4 | V | |
| V _{OH} | High-level output voltage | I _{OH} = –50 μA | 0.9V _{CC} | | | V | |
| | | I _{OH} = –2 mA | 2.4 | | | V | |
| I _I | Input current | MC | 0 V ≤ V _I ≤ 0.3 V | | | 10 | μA |
| | | | 0.3 V < V _I ≤ 13 V | | | 650 | μA |
| | | | 12 V ≤ V _I ≤ 13 V (see Note 1) | | | 50 | mA |
| | I/O pins | 0 V ≤ V _I ≤ V _{CC1} | | | ± 10 | μA | |
| I _{OL} | Low-level output current | V _{OL} = 0.4 V | 1.4 | | | mA | |
| I _{OH} | High-level output current | V _{OH} = 0.9V _{CC1} | –50 | | | μA | |
| | | V _{OH} = 2.4 V | –2 | | | mA | |
| I _{CC1} | Supply current (operating mode) OSC POWER bit = 0 | See Notes 2 and 3 SYSCLK = 5 MHz | | 35 | 45 | mA | |
| | | See Notes 2 and 3 SYSCLK = 3 MHz | | 25 | 35 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 10 | 14 | mA | |
| I _{CC1} | Supply current (STANDBY mode) OSC POWER bit = 0 | See Notes 2 and 3 SYSCLK = 5 MHz | | 12 | 17 | mA | |
| | | See Notes 2 and 3 SYSCLK = 3 MHz | | 8 | 13 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 3 | 4 | mA | |
| I _{CC1} | Supply current (STANDBY mode) OSC POWER bit = 1 | See Notes 2 and 3 SYSCLK = 3 MHz | | 6 | 8.6 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 2 | 3.0 | mA | |
| I _{CC1} | Supply current (HALT mode) | See Note 2 XTAL2/CLKIN < 0.2 V | | 15 | 40 | μA | |

- Notes:**
- 1) Input current I_{pp} is a maximum of 50 mA only when EPROM is being programmed.
 - 2) Single-chip mode, ports configured as inputs or as outputs with no load. All inputs ≤ 0.2 V or ≥ V_{CC1} – 0.2 V.
 - 3) XTAL2/CLKIN is driven with an external square wave signal with 50% duty cycle and rise and fall times less than 10 ns. Current can be higher with a crystal oscillator. At 5-MHz SYSCLK, this extra current = 0.01 mA × (total load capacitance + crystal capacitance in pF).

18.10.2 TMS370Cx32A Timings

Refer to Sections 18.1 and 18.2 (both on page 18-2) for timing symbol definitions and parameter measurement points.

Table 18–23. External Clocking Requirements For Divide-by-4 Clock (See Note 1)

| No. | Parameter | Min | Max | Unit | |
|-----|--|--|-----|------|-----|
| 1 | $t_{w(Cl)}$ Pulse duration, XTAL2/CLKIN (see Note 2) | 20 | | ns | |
| 2 | $t_{r(Cl)}$ Rise time, XTAL2/CLKIN | | 30 | ns | |
| 3 | $t_{f(Cl)}$ Fall time, XTAL2/CLKIN | | 30 | ns | |
| 4 | $t_{d(ClH-SCL)}$ Delay time, XTAL2/CLKIN rise to SYSCLK fall | | 100 | ns | |
| | CLKIN | Crystal operating frequency | 2 | 20 | MHz |
| | SYSCLK | Internal system clock operating frequency (see Note 3) | 0.5 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–21.
 - 2) This pulse may be either a high pulse, as illustrated in Figure 18–15, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/4$

Figure 18–15. External Clock Timing for Divide-by-4 Clock

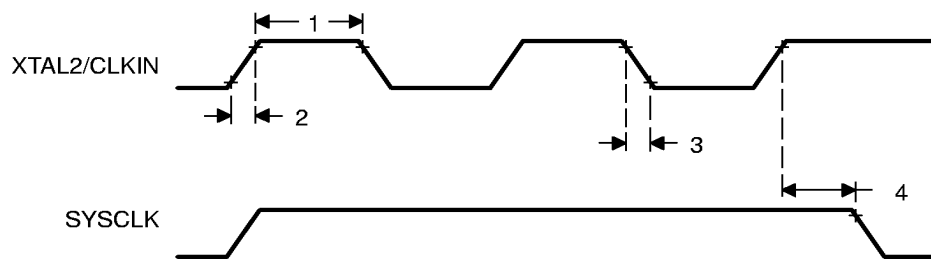


Table 18–24. External Clocking Requirements for Divide-by-1 Clock (PLL) (See Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|----------------|-----|-----|------|
| 1 | $t_{w(CI)}$ | 20 | | ns |
| 2 | $t_r(CI)$ | | 30 | ns |
| 3 | $t_f(CI)$ | | 30 | ns |
| 4 | $t_d(CIH-SCH)$ | | 100 | ns |
| | CLKIN | 2 | 5 | MHz |
| | SYSCLK | 2 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–21.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–16, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/1$

Figure 18–16. External Clock Timing for Divide-by-1 Clock

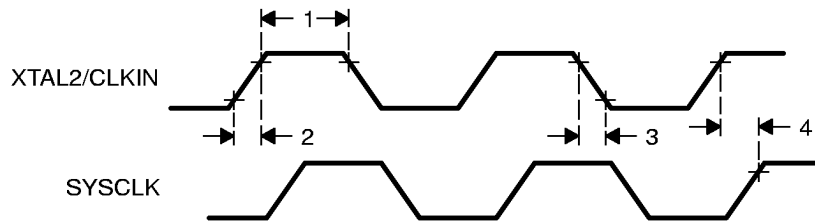
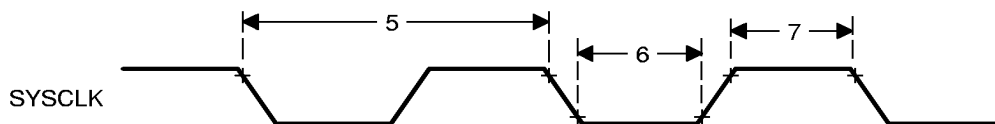


Table 18–25. Switching Characteristics and Timing Requirements (See Note)

| No. | Parameter | Min | Max | Unit | |
|-----|--------------|-------------------|---------------|------|----|
| 5 | t_c | Divide-by-4 clock | 200 | 2000 | ns |
| | | Divide-by-1 clock | 200 | 500 | |
| 6 | $t_{w(SCL)}$ | $0.5t_c - 20$ | $0.5t_c$ | ns | |
| 7 | $t_{w(SCH)}$ | $0.5t_c$ | $0.5t_c + 20$ | ns | |

Note: $t_c =$ system clock cycle time = $1 / SYSCLK$

Figure 18–17. SYSCLK Timing



18.11 TMS370Cx36A Specifications

The tables in this section give specifications that apply to the devices in the TMS370Cx36A category. These devices include the TMS370C036A, TMS370C736A, and SE370C736A.

18.11.1 TMS370Cx36A Electrical Specifications

Stresses beyond those listed in Table 18–1 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the recommended operating conditions in Table 18–26 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



Table 18–26. Recommended Operating Conditions (See Note 1)

| Parameter | | Min | Nom | Max | Unit | |
|---------------------|--|--|---------------------|------------------|------------------|----|
| V _{CC1} | Supply voltage | 4.5 | 5 | 5.5 | V | |
| | RAM data-retention supply voltage (see Note 2) | 3 | | 5.5 | V | |
| V _{CCSTBY} | Standby RAM supply voltage | 4.5 | 5 | 5.5 | V | |
| V _{CCSTBY} | Standby RAM data retention supply voltage (see Note 2) | 3 | | 5.5 | V | |
| V _{CC3} | Analog supply voltage | 4.5 | 5 | 5.5 | V | |
| V _{SS3} | Analog supply ground | –0.3 | 0 | 0.3 | V | |
| V _{IL} | Low-level input voltage | All pins except MC | | V _{SS1} | 0.8 | V |
| | | MC, normal operation | | V _{SS1} | 0.3 | V |
| V _{IH} | High-level input voltage | All pins except MC, XTAL2/CLKIN, and $\overline{\text{RESET}}$ | 2 | | V _{CC1} | V |
| | | XTAL2/CLKIN | 0.8V _{CC1} | | V _{CC1} | V |
| | | $\overline{\text{RESET}}$ | 0.7V _{CC1} | | V _{CC1} | V |
| V _{MC} | MC (mode control) voltage | EEPROM write-protect override (WPO) mode | 11.7 | 12 | 13 | V |
| | | EPRM programming voltage (V _{PP}) | 13 | 13.2 | 13.5 | V |
| | | Microcomputer mode | V _{SS1} | | 0.3 | V |
| T _A | Operating free-air temperature | L version | 0 | | 70 | °C |
| | | A version | –40 | | 85 | °C |
| | | T version | –40 | | 105 | °C |

- Notes:** 1) Unless otherwise noted, all voltage values are with respect to V_{SS1}.
2) $\overline{\text{RESET}}$ must be externally activated when V_{CC1} or SYSCLK is not within the recommended operating range.



Table 18–27. Electrical Characteristics Over Recommended Operating Free-Air Temperature Range

| Parameter | | Test Conditions | Min | Typ | Max | Unit |
|--------------|---|--|---|--------------|----------|---------------|
| V_{OL} | Low-level output voltage, all outputs | $I_{OL} = 1.4 \text{ mA}$ | | | 0.4 | V |
| V_{OH} | High-level output voltage | All outputs except PACT outputs | $I_{OH} = -50 \mu\text{A}$ | $0.9V_{CC1}$ | | V |
| | | PACT outputs | $I_{OH} = -50 \mu\text{A}$ | $0.7V_{CC1}$ | | V |
| | | All outputs | $I_{OH} = -2 \text{ mA}$ | 2.4 | | V |
| I_I | Input current | MC pin | $0 \text{ V} < V_I < 0.3 \text{ V}$ | | 10 | μA |
| | | | $0.3 \text{ V} < V_I < V_{CC1} - 0.3 \text{ V}$ | | 50 | μA |
| | | | $V_{CC1} - 0.3 < V_I < V_{CC1} + 0.3 \text{ V}$ | | 10 | μA |
| | | | $V_{CC1} + 0.3 \text{ V} < V_I < 13 \text{ V}$ | | 650 | μA |
| | | I/O pins | $0 \text{ V} < V_I < V_{CC1}$ | | ± 10 | μA |
| I_{OL} | Low-level output current, all outputs | $V_{OL} = 0.4 \text{ V}$ | 1.4 | | | mA |
| I_{OH} | High-level output current, all outputs | $V_{OH} = 0.9 V_{CC1}$ | -50 | | | μA |
| | | $V_{OH} = 2.4 \text{ V}$ | -2 | | | mA |
| I_{CC1} | Supply current (operating mode) OSC POWER bit = 0 | See Notes 1 and 2 SYSCLK = 5 MHz | | 36 | 45 | mA |
| | Supply current (STANDBY mode) OSC POWER bit = 0 | See Notes 1 and 2 SYSCLK = 5 MHz | | 7 | 12 | mA |
| | Supply current (HALT mode) | See Notes 1 and 2 XTAL2/CLKIN < 0.2 V | | 5 | 30 | μA |
| I_{CCSTBY} | Standby RAM supply current (operating mode) OSC POWER bit = 0 | SYSCLK = 5 MHz $V_{CCSTBY} = 4.5 \text{ V}$ | | 1 | 1.5 | mA |

- Notes:**
- 1) Single-chip mode, ports configured as inputs or as outputs with no load. All inputs $\leq 0.2 \text{ V}$ or $\geq V_{CC1} - 0.2 \text{ V}$.
 - 2) XTAL2/CLKIN is driven with an external square wave signal with 50% duty cycle and rise and fall times less than 10 ns. Current can be higher with a crystal oscillator. At 5-MHz SYSCLK, this extra current = $0.01 \text{ mA} \times (\text{total load capacitance} + \text{crystal capacitance in pF})$.



18.11.2 TMS370Cx36A Timings

Refer to Sections 18.1 and 18.2 (both on page 18-2) for timing symbol definitions and parameter measurement points.

Table 18–28. External Clocking Requirements for Divide-by-4 Clock (See Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|------------------|-----|-----|------|
| 1 | $t_{w(CI)}$ | 20 | | ns |
| 2 | $t_{r(CI)}$ | | 30 | ns |
| 3 | $t_{f(CI)}$ | | 30 | ns |
| 4 | $t_{d(CIH-SCL)}$ | | 100 | ns |
| | CLKIN | 2 | 20 | MHz |
| | SYSCLK | 0.5 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–26.
 - 2) This pulse may be either a high pulse, as illustrated in Figure 18–18, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/4$

Figure 18–18. External Clock Timing for Divide-by-4 Clock

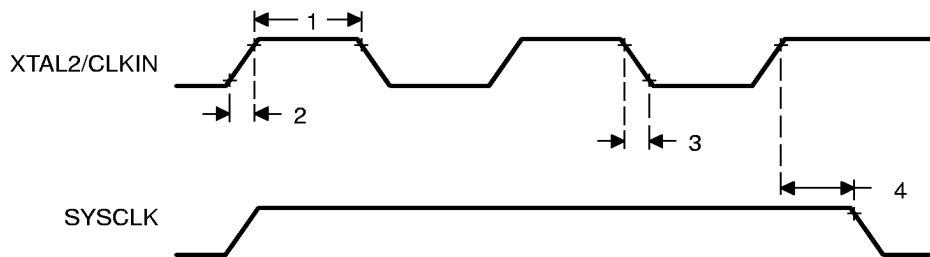


Table 18–29. External Clocking Requirements For Divide-by-1 Clock (PLL) (See Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|------------------|-----|-----|------|
| 1 | $t_{w(CI)}$ | 20 | | ns |
| 2 | $t_{r(CI)}$ | | 30 | ns |
| 3 | $t_{f(CI)}$ | | 30 | ns |
| 4 | $t_{d(CIH-SCH)}$ | | 100 | ns |
| | CLKIN | 2 | 5 | MHz |
| | SYSCLK | 2 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–26.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–19, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/1$

Figure 18–19. External Clock Timing for Divide-by-1 Clock

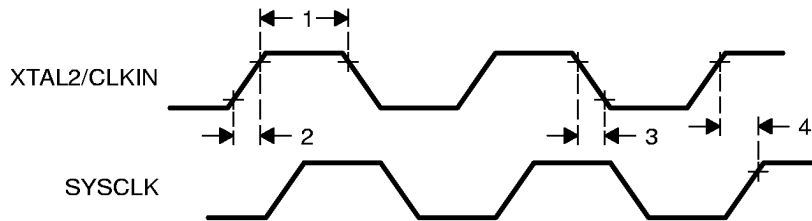
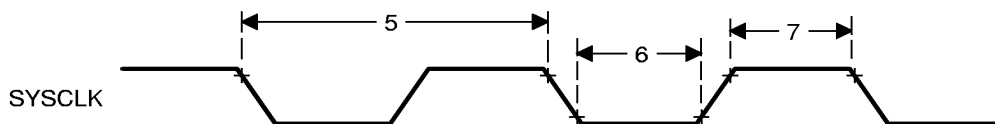


Table 18–30. Switching Characteristics and Timing Requirements (See Note)

| No. | Parameter | Min | Max | Unit | | |
|-----|--------------|-----------------------------|-------------------|---------------|---------------|----|
| 5 | t_c | Cycle time, SYSCLK | Divide-by-4 clock | 200 | 2000 | ns |
| | | | Divide-by-1 clock | 200 | 500 | ns |
| 6 | $t_{w(SCL)}$ | Pulse duration, SYSCLK low | | $0.5t_c - 20$ | $0.5t_c$ | ns |
| 7 | $t_{w(SCH)}$ | Pulse duration, SYSCLK high | | $0.5t_c$ | $0.5t_c + 20$ | ns |

Note: $t_c =$ system clock cycle time = $1/SYSCLK$

Figure 18–20. SYSCLK Timing



18.12 TMS370Cx4xA Specifications

The tables in this section give specifications that apply to the devices in the TMS370Cx4xA category. These devices include the TMS370C040A, TMS370C042A, TMS370C340A, TMS370C342A, TMS370C742A, and SE370C742A.

18.12.1 TMS370Cx4xA Electrical Specifications

Stresses beyond those listed in Table 18–1 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the recommended operating conditions in Table 18–31 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



Table 18–31. Recommended Operating Conditions (See Note 1)

| Parameter | | Min | Nom | Max | Unit | |
|------------------|--|--|--------------------|-----------------|------|---|
| V _{CC} | Supply voltage | 4.5 | 5 | 5.5 | V | |
| | RAM data-retention supply voltage (see Note 2) | 3 | | 5.5 | V | |
| V _{CC3} | Analog supply voltage | 4.5 | 5 | 5.5 | V | |
| V _{SS3} | Analog supply ground | –0.3 | 0 | 0.3 | V | |
| V _{IL} | Low-level input voltage | All pins except MC | V _{SS} | 0.8 | V | |
| | | MC, normal operation | V _{SS} | 0.3 | V | |
| V _{IH} | High-level input voltage | All pins except MC, XTAL2/CLKIN, and RESET | 2 | V _{CC} | V | |
| | | XTAL2/CLKIN | 0.8V _{CC} | V _{CC} | V | |
| | | $\overline{\text{RESET}}$ | 0.7V _{CC} | V _{CC} | V | |
| V _{MC} | MC (mode control) voltage | EEPROM write-protect override (WPO) mode | 11.7 | 12 | 13 | V |
| | | Microcomputer mode | V _{SS} | | 0.3 | V |
| | | EPROM programming voltage (V _{PP}) | 13 | 13.2 | 13.5 | V |
| T _A | Operating free-air temperature | L version | 0 | 70 | °C | |
| | | A version | –40 | 85 | °C | |
| | | T version | –40 | 105 | °C | |

- Notes:**
- 1) Unless otherwise noted, all voltage values are with respect to V_{SS} (ground).
 - 2) $\overline{\text{RESET}}$ must be externally activated when V_{CC} or SYSCLK is out of the recommended operating range.



Table 18–32. Electrical Characteristics Over Recommended Operating Free-Air Temperature Range

| Parameter | | Test Conditions | Min | Typ | Max | Unit | |
|-----------------|---|--|---|-----|-----|------|----|
| V _{OL} | Low-level digital output voltage | I _{OL} = 1.4 mA | | | 0.4 | V | |
| V _{OH} | High-level output voltage | I _{OH} = –50 μA | 0.9V _{CC} | | | V | |
| | | I _{OH} = –2 mA | 2.4 | | | V | |
| I _I | Input current | MC | 0 V < V _I ≤ 0.3 V | | | 10 | μA |
| | | | 0.3 V < V _I ≤ 13 V | | | 650 | μA |
| | | | 12 V ≤ V _I ≤ 13 V (see Note 6) | | | 50 | mA |
| | I/O pins | 0 V ≤ V _I ≤ V _{CC} | | | ±10 | μA | |
| I _{OL} | Low-level output current | V _{OL} = 0.4 V | 1.4 | | | mA | |
| I _{OH} | High-level output current | V _{OH} = 0.9V _{CC} | –50 | | | μA | |
| | | V _{OH} = 2.4 V | –2 | | | mA | |
| I _{CC} | Supply current (operating mode) OSC POWER bit = 0 (see Note 3) | See Notes 1 and 2 SYSCLK = 5 MHz | | 30 | 45 | mA | |
| | | See Notes 1 and 2 SYSCLK = 3 MHz | | 20 | 30 | mA | |
| | | See Notes 1 and 2 SYSCLK = 0.5 MHz | | 7 | 11 | mA | |
| I _{CC} | Supply current (STANDBY mode) OSC POWER bit = 0 (see Note 4) | See Notes 1 and 2 SYSCLK = 5 MHz | | 10 | 17 | mA | |
| | | See Notes 1 and 2 SYSCLK = 3 MHz | | 8 | 11 | mA | |
| | | See Notes 1 and 2 SYSCLK = 0.5 MHz | | 2 | 3.5 | mA | |
| I _{CC} | Supply current (STANDBY mode) OSC POWER bit = 1 (see Note 5) | See Notes 1 and 2 SYSCLK = 3 MHz | | 6 | 8.6 | mA | |
| | | See Notes 1 and 2 SYSCLK = 0.5 MHz | | 2 | 3.0 | mA | |
| I _{CC} | Supply current (HALT mode) | See Note 1 XTALK2/CLKIN < 0.2 V | | 2 | 30 | μA | |

- Notes:**
- 1) Microcontroller single-chip mode, ports configured as inputs or as outputs with no load. All inputs ≤ 0.2 V or ≥ V_{CC} – 0.2 V.
 - 2) XTAL2/CLKIN is driven with an external square wave signal with 50% duty cycle and rise and fall times less than 10 ns. Current can be higher with a crystal oscillator. At 5-MHz SYSCLK this extra current = 0.01 mA × (total load capacitance + crystal capacitance in pF).
 - 3) Maximum operating current = 7.6(SYSCLK) + 7 mA.
 - 4) Maximum standby current = 3(SYSCLK) + 2 mA (OSC POWER bit = 0.)
 - 5) Maximum standby current = 2.24(SYSCLK) + 1.9 mA (OSC POWER bit = 1; valid only up to 3-MHz SYSCLK.)
 - 6) Input current I_{pp} is a maximum of 50 mA only when an EPROM is being programmed.

18.12.2 TMS370Cx4xA Timings

Refer to Sections 18.1 and 18.2 (both on page 18-2) for timing symbol definitions and parameter measurement points.

Table 18–33. External Clocking Requirements for Divide-by-4 Clock (See Note 1)

| No. | Parameter | Min | Max | Unit | |
|-----|--|--|-----|------|-----|
| 1 | $t_{w(Cl)}$ Pulse duration, XTAL2/CLKIN (see Note 2) | 20 | | ns | |
| 2 | $t_{r(Cl)}$ Rise time, XTAL2/CLKIN | | 30 | ns | |
| 3 | $t_{f(Cl)}$ Fall time, XTAL2/CLKIN | | 30 | ns | |
| 4 | $t_{d(CIH-SCL)}$ Delay time, XTAL2/CLKIN rise to SYSCLK fall | | 100 | ns | |
| | CLKIN | Crystal operating frequency | 2 | 20 | MHz |
| | SYSCLK | Internal system clock operating frequency (see Note 3) | 0.5 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–31.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–21, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/4$

Figure 18–21. External Clock Timing for Divide-by-4 Clock

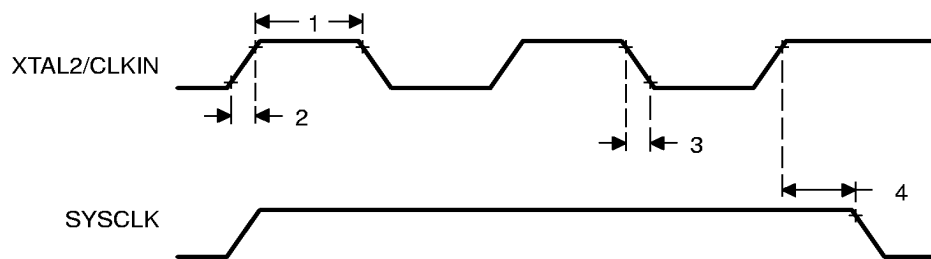


Table 18–34. External Clocking Requirements for Divide-by-1 Clock (PLL) (See Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|------------------|-----|-----|------|
| 1 | $t_{w(CI)}$ | 20 | | ns |
| 2 | $t_{r(CI)}$ | | 30 | ns |
| 3 | $t_{f(CI)}$ | | 30 | ns |
| 4 | $t_{d(CIH-SCH)}$ | | 100 | ns |
| | CLKIN | 2 | 5 | MHz |
| | SYSCLK | 2 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–31.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–22, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/1$

Figure 18–22. External Clock Timing for Divide-by-1 Clock

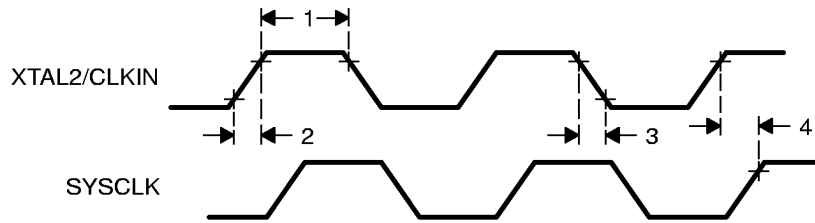
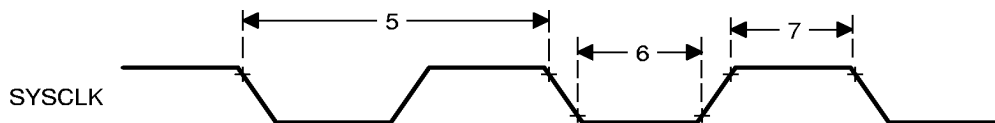


Table 18–35. Switching Characteristics and Timing Requirements (See Note)

| No. | Parameter | Min | Max | Unit | |
|-----|--------------|--------------------|---------------|------|----|
| 5 | t_c | Cycle time, SYSCLK | | | |
| | | Divide-by-4 clock | 200 | 2000 | ns |
| | | Divide-by-1 clock | 200 | 500 | ns |
| 6 | $t_{w(SCL)}$ | $0.5t_c - 20$ | $0.5t_c$ | ns | |
| 7 | $t_{w(SCH)}$ | $0.5t_c$ | $0.5t_c + 20$ | ns | |

Note: $t_c = \text{system-clock cycle time} = 1/SYSCLK$.

Figure 18–23. SYSCLK Timing



18.13 TMS370Cx5xA and TMS370Cx5xB Specifications

The tables in this section give specifications that apply to the devices in the TMS370Cx5xA and TMS370Cx5xB categories. These devices include the following:

| | | | |
|-------------|-------------|--------------|-------------|
| TMS370C050A | TMS370C150A | TMS370C250A | TMS370C350A |
| TMS370C052A | TMS370C352A | TMS370C452A | TMS370C353A |
| TMS370C056A | TMS370C156A | TMS370C256A | TMS370C356A |
| TMS370C456A | TMS370C756A | SE370C756A | TMS370C058A |
| TMS370C358A | TMS370C758A | TMS370C758B, | SE370C758A |
| SE370758B | TMS370C059A | TMS370C759A | SE370C759A |

Note:

Some electrical specifications and timings differ for TMS370Cx5x devices. Refer to Appendix A.

18.13.1 TMS370Cx5xA and TMS370Cx5xB Electrical Specifications

Stresses beyond those listed in Table 18–1 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the recommended operating conditions in Table 18–36 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



Table 18–36. Recommended Operating Conditions (See Note 1)

| Parameter | | Min | Nom | Max | Unit | |
|------------------|--|--|-----------------------|-----------------------|-----------------------|---|
| V _{CC1} | Supply voltage | 4.5 | 5 | 5.5 | V | |
| | RAM data-retention supply voltage (see Note 2) | 3 | | 5.5 | V | |
| V _{CC2} | Digital I/O supply voltage | 4.5 | 5 | 5.5 | V | |
| V _{CC3} | Analog supply voltage | 4.5 | 5 | 5.5 | V | |
| V _{SS2} | Digital I/O supply ground | –0.3 | 0 | 0.3 | V | |
| V _{SS3} | Analog supply ground | –0.3 | 0 | 0.3 | V | |
| V _{IL} | Low-level input voltage | All pins except MC | V _{SS1} | 0.8 | V | |
| | | MC, normal operation | V _{SS1} | 0.3 | V | |
| V _{IH} | High-level input voltage | All pins except MC, XTAL2/CLKIN, and RESET | 2 | V _{CC1} | V | |
| | | MC (non-WPO mode) | V _{CC1} –0.3 | V _{CC1} +0.3 | V | |
| | | XTAL2/CLKIN | 0.8V _{CC1} | V _{CC1} | V | |
| | | RESET | 0.7V _{CC1} | V _{CC1} | V | |
| V _{MC} | MC (mode control) voltage (see Note 3) | EEPROM write-protect override (WPO) mode | 11.7 | 12 | 13 | V |
| | | EPROM programming voltage (V _{PP}) | 13 | 13.2 | 13.5 | V |
| | | Microprocessor mode | V _{CC1} –0.3 | | V _{CC1} +0.3 | V |
| | | Microcomputer mode | V _{SS1} | | 0.3 | V |
| T _A | Operating free-air temperature | L version | 0 | 70 | °C | |
| | | A version | –40 | 85 | °C | |
| | | T version | –40 | 105 | °C | |

- Notes:**
- 1) Unless otherwise noted, all voltage values are with respect to V_{SS1}.
 - 2) RESET must be externally activated when V_{CC1} or SYSCLK is not within the recommended operating range.
 - 3) The basic microcomputer and microprocessor operating modes are selected by the voltage level applied to the dedicated MC pin two system-clock cycles (2t_c) before RESET goes inactive (high). The WPO mode can be selected any time a sufficient voltage is present on MC.

CAUTION

You cannot use the internal connectors between pins (e.g., the connector between V_{SS1} and V_{SS2}) for a jumper from one side of the chip to another.

Table 18–37. Electrical Characteristics Over Recommended Operating Free-Air Temperature Range

| Parameter | | | Test Conditions | Min | Typ | Max | Unit |
|------------------|--|--|--|--------------------|-----|-----|------|
| V _{OL} | Low-level output voltage (see Note 1) | | I _{OL} = 1.4 mA | | | 0.4 | V |
| V _{OH} | High-level output voltage | | I _{OH} = –50 μA | 0.9V _{CC} | | | V |
| | | | I _{OH} = –2 mA | 2.4 | | | V |
| I _I | Input current | MC | 0 V < V _I ≤ 0.3 V | | | 10 | μA |
| | | | 0.3 V < V _I < V _{CC1} – 0.3 V | | | 50 | μA |
| | | | V _{CC1} – 0.3 V ≤ V _I ≤ V _{CC1} + 0.3 V | | | 10 | μA |
| | | | V _{CC1} + 0.3 V < V _I ≤ 13 V | | | 650 | μA |
| | | | 12 V ≤ V _I ≤ 13 V (see Note 2) | | | 50 | mA |
| | I/O pins | 0 V ≤ V _I ≤ V _{CC1} | | | | ±10 | μA |
| I _{OL} | Low-level output current (see Note 1) | | V _{OL} = 0.4 V | 1.4 | | | mA |
| I _{OH} | High-level output current | | V _{OH} = 0.9V _{CC1} | –50 | | | μA |
| | | | V _{OH} = 2.4 V | –2 | | | mA |
| I _{CC1} | Supply current (operating mode) OSC POWER bit = 0 (see Note 5) | TMS370Cx50A TMS370Cx52A | See Notes 3 and 4 SYSCLK = 5 MHz | | 30 | 45 | mA |
| | | TMS370Cx53A TMS370Cx56A TMS370Cx58A TMS370Cx58B | | | 35 | 56 | mA |

† TMS370Cx59 operates only up to 3-MHz SYSCLK.

- Notes:**
- 1) In prior versions of the TMS370 family, I_{OL} was equal to 2 mA for ports A, B, C, and D and RESET.
 - 2) Input current I_{pp} is a maximum of 50 mA only when EPROM is being programmed.
 - 3) Single-chip mode, ports configured as inputs or as outputs with no load. All inputs ≤ 0.2 V or ≥ V_{CC1} – 0.2 V.
 - 4) XTAL2/CLKIN is driven with an external square wave signal with 50% duty cycle and rise and fall times less than 10 ns. Current can be higher with a crystal oscillator. At 5-MHz SYSCLK, this extra current = 0.01 mA × (total load capacitance + crystal capacitance in pF).
 - 5) Maximum operating current for TMS370Cx50A and TMS370Cx52A = 7.6(SYSCLK) + 7 mA. Maximum operating current for the 'Cx53A, 'Cx56A, 'Cx58A, and 'Cx58B = 10(SYSCLK) + 5.8 mA.
 - 6) Maximum standby current for the 'Cx5xA and 'Cx5xB = 3(SYSCLK) + 2 mA (OSC POWER bit = 0).
 - 7) Maximum standby current for the 'Cx5xA and 'Cx5xB = 2.24(SYSCLK) + 1.9 mA (OSC POWER bit = 1; valid only up to 3-MHz SYSCLK.)



Table 18–37. Electrical Characteristics Over Recommended Operating Free-Air Temperature Range (Continued)

| Parameter | | Test Conditions | Min | Typ | Max | Unit | |
|------------------|---|--|---------------------------------------|---------------------------------------|---------------------------------------|------|-----|
| I _{CC1} | Supply current (operating mode) OSC POWER bit = 0 (see Note 5) | TMS370Cx50A TMS370Cx52A | See Notes 3 and 4 SYSCLK = 3 MHz | 20 | 30 | mA | |
| | | TMS370Cx53A TMS370Cx56A TMS370Cx58A TMS370Cx58B | | 25 | 36 | mA | |
| | | TMS370Cx59A† | | 46 | 55 | mA | |
| I _{CC1} | Supply current (operating mode) OSC POWER bit = 0 (see Note 5) | TMS370Cx50A TMS370Cx52A | See Notes 3 and 4 SYSCLK = 0.5 MHz | 5 | 11 | mA | |
| | | TMS370Cx53A TMS370Cx56A TMS370Cx58A TMS370Cx58B | | 13 | 18 | mA | |
| | | TMS370Cx59A† | | 22 | 28 | mA | |
| I _{CC1} | Supply current (STANDBY mode) OSC POWER bit = 0 (see Note 6) | | See Notes 3 and 4 SYSCLK = 5 MHz | 12 | 17 | mA | |
| | | | | See Notes 3 and 4 SYSCLK = 3 MHz | 8 | 11 | mA |
| | | | | | See Notes 3 and 4 SYSCLK = 0.5 MHz | 2.5 | 3.5 |
| I _{CC1} | Supply current (STANDBY mode) OSC POWER bit = 1 (see Note 7) | | See Notes 3 and 4 SYSCLK = 3 MHz | 6 | 8.6 | mA | |
| | | | | See Notes 3 and 4 SYSCLK = 0.5 MHz | 2 | 3 | mA |
| I _{CC1} | Supply current (HALT mode) | | See Note 3 XTAL2/CLKIN < 0.2 V | 2 | 30 | μA | |

† TMS370Cx59A operates only up to 3-MHz SYSCLK.

- Notes:**
- 1) I then prior versions of the TMS370 family, I_{OL} was equal to 2 mA for ports A, B, C, and D and $\overline{\text{RESET}}$.
 - 2) Input current I_{pp} is a maximum of 50 mA only when EPROM is being programmed.
 - 3) Single-chip mode, ports configured as inputs or as outputs with no load. All inputs ≤ 0.2 V or $\geq V_{CC1} - 0.2$ V.
 - 4) XTAL2/CLKIN is driven with an external square wave signal with 50% duty cycle and rise and fall times less than 10 ns. Current can be higher with a crystal oscillator. At 5-MHz SYSCLK, this extra current = 0.01 mA × (total load capacitance + crystal capacitance in pF).
 - 5) Maximum operating current for the 'Cx50A and 'Cx52A = 7.6(SYSCLK) + 7 mA. Maximum operating current for the 'Cx53A, 'Cx56A, 'Cx58A and 'Cx58B = 10(SYSCLK) + 5.8 mA.
 - 6) Maximum standby current for the 'Cx5xA and 'Cx5xB = 3(SYSCLK) + 2 mA (OSC POWER bit = 0).
 - 7) Maximum standby current for the 'Cx5xA and 'Cx5xB = 2.24(SYSCLK) + 1.9 mA (OSC POWER bit = 1; valid only up to 3-MHz SYSCLK.)

18.13.2 TMS370Cx5xA and TMS370Cx5xB Timings

Refer to Sections 18.1 and 18.2 (both on page 18-2) for timing symbol definitions and parameter measurement points.

Table 18–38. External Clocking Requirements for Divide-by-4 Clock (See Note 1)

| No. | Parameter | Min | Max | Unit | |
|-----|--|---|-----|------|-----|
| 1 | $t_{w(Cl)}$ Pulse duration, XTAL2/CLKIN (see Note 2) | 20 | | ns | |
| 2 | $t_{r(Cl)}$ Rise time, XTAL2/CLKIN | | 30 | ns | |
| 3 | $t_{f(Cl)}$ Fall time, XTAL2/CLKIN | | 30 | ns | |
| 4 | $t_{d(CIH-SCL)}$ Delay time, XTAL2/CLKIN rise to SYSCLK fall | | 100 | ns | |
| | CLKIN | Crystal operating frequency (see Note 3) | 2 | 20 | MHz |
| | SYSCLK | Internal system clock operating frequency (see Notes 4 and 5) | 0.5 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–36.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–24, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle, or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) TMS370Cx59A operates up to 12-MHz CLKIN.
 - 4) TMS370Cx59A operates up to 3-MHz SYSCLK.
 - 5) SYSCLK = CLKIN/4

Figure 18–24. External Clock Timing for Divide-by-4 Clock

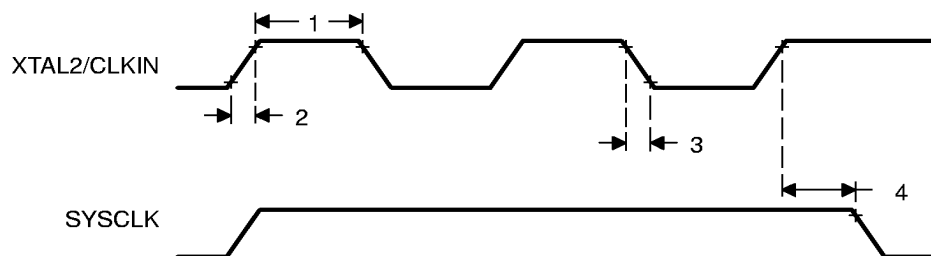


Table 18–39. External Clocking Requirements for Divide-by-1 Clock (PLL) (see Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|------------------|-----|-----|------|
| 1 | $t_{w(CI)}$ | 20 | | ns |
| 2 | $t_{r(CI)}$ | | 30 | ns |
| 3 | $t_{f(CI)}$ | | 30 | ns |
| 4 | $t_{d(CIH-SCH)}$ | | 100 | ns |
| | CLKIN | 2 | 5 | MHz |
| | SYSCLK | 2 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–36.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–25, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle, or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) TMS370Cx59A operates up to 3-MHz CLKIN (for the divide-by-1 clock option).
 - 4) TMS370Cx59A operates up to 3-MHz SYSCLK.
 - 5) $SYSCLK = CLKIN/1$

Figure 18–25. External Clock Timing for Divide-by-1 Clock

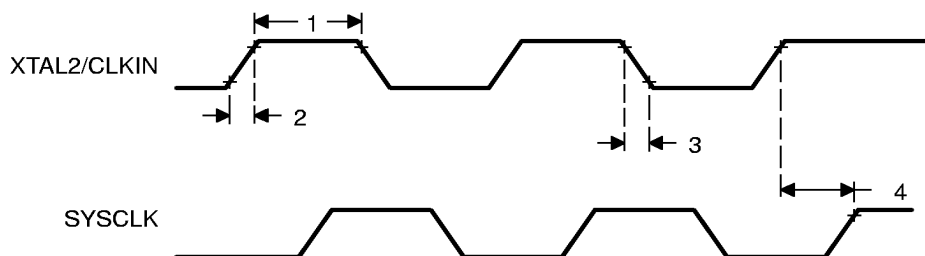


Table 18–40. Switching Characteristics and Timing Requirements for External Read and Write (See Note 1)

| No. | Parameter | Min | Max | Unit | | |
|-----|-----------------------------|---|-------------------------|------------------------------|------------------------------|----|
| 5 | t_c | Cycle time, SYSCLK | Divide-by-4 clock | 200 | 2000 | ns |
| | | | Divide-by-1 clock (PLL) | 200 | 500 | ns |
| 6 | $t_w(\text{SCL})$ | Pulse duration, SYSCLK low | | $0.5t_c - 25$ | $0.5t_c$ | ns |
| 7 | $t_w(\text{SCH})$ | Pulse duration, SYSCLK high | | $0.5t_c$ | $0.5t_c + 20$ | ns |
| 8 | $t_d(\text{SCL-A})$ | Delay time, SYSCLK low to address, $\overline{\text{R}}/\overline{\text{W}}$, and $\overline{\text{OCF}}$ valid | | | $0.25t_c + 75$ | ns |
| 9 | $t_v(\text{A})$ | Valid time, address valid to $\overline{\text{EDS}}$, $\overline{\text{CSE1}}$, $\overline{\text{CSE2}}$, $\overline{\text{CSH1}}$, $\overline{\text{CSH2}}$, $\overline{\text{CSH3}}$, and $\overline{\text{CSPF}}$ low | | $0.5t_c - 90$ | | ns |
| 10 | $t_{su}(\text{D})$ | Setup time, write data to $\overline{\text{EDS}}$ high | | $0.75t_c - 80$ See Note 2 | | ns |
| 11 | $t_h(\text{EH-A})$ | Hold time, address, $\overline{\text{R}}/\overline{\text{W}}$, and $\overline{\text{OCF}}$ from $\overline{\text{EDS}}$, $\overline{\text{CSE1}}$, $\overline{\text{CSE2}}$, $\overline{\text{CSH1}}$, $\overline{\text{CSH2}}$, $\overline{\text{CSH3}}$, and $\overline{\text{CSPF}}$ high | | $0.5t_c - 60$ | | ns |
| 12 | $t_h(\text{EH-D})\text{W}$ | Hold time, write data from $\overline{\text{EDS}}$ high | | $0.75t_c + 15$ | | ns |
| 13 | $t_d(\text{DZ-EL})$ | Delay time, data bus high impedance to $\overline{\text{EDS}}$ low (read cycle) | | $0.25t_c - 35$ | | ns |
| 14 | $t_d(\text{EH-D})$ | Delay time, $\overline{\text{EDS}}$ high to data bus enable (read cycle) | | $1.25t_c - 40$ | | ns |
| 15 | $t_d(\text{EL-DV})\text{R}$ | Delay time, $\overline{\text{EDS}}$ low to read data valid | | | $t_c - 95$ See Note 2 | ns |
| 16 | $t_h(\text{EH-D})\text{R}$ | Hold time, read from $\overline{\text{EDS}}$ high | | 0 | | ns |
| 17 | $t_{su}(\text{WT-SCH})$ | Setup time, $\overline{\text{WAIT}}$ to SYSCLK high | | $0.25t_c + 70$ See Note 3 | | ns |
| 18 | $t_h(\text{SCH-WT})$ | Hold time, $\overline{\text{WAIT}}$ time from SYSCLK high | | 0 | | ns |
| 19 | $t_d(\text{EL-WTV})$ | Delay time, $\overline{\text{EDS}}$ low to $\overline{\text{WAIT}}$ valid | | | $0.5t_c - 60$ | ns |
| 20 | t_w | Pulse duration, $\overline{\text{EDS}}$, $\overline{\text{CSE1}}$, $\overline{\text{CSE2}}$, $\overline{\text{CSH1}}$, $\overline{\text{CSH2}}$, $\overline{\text{CSH3}}$, and $\overline{\text{CSPF}}$ low | | $t_c - 80$ See Note 2 | $t_c + 40$ See Note 2 | ns |
| 21 | $t_d(\text{AV-DV})\text{R}$ | Delay time, address valid to read data valid | | | $1.5t_c - 115$ See Note 2 | ns |
| 22 | $t_d(\text{AV-WTV})$ | Delay time, address valid to $\overline{\text{WAIT}}$ valid | | | $t_c - 115$ | ns |
| 23 | $t_d(\text{AV-EH})$ | Delay time, address valid to $\overline{\text{EDS}}$ high (end of write) | | $1.5t_c - 85$ See Note 2 | | ns |

- Notes:**
- 1) t_c = system-clock cycle time = 1/SYSCLK
 - 2) If wait states, PFWait, or the autowait feature is used, add t_c to this value for each wait state invoked.
 - 3) If the autowait feature is enabled, the $\overline{\text{WAIT}}$ input can assume a "don't care" condition until the third cycle of the access. The $\overline{\text{WAIT}}$ signal must be synchronized with the high pulse of the SYSCLK signal while still conforming to the minimum setup time.



Figure 18–26. External Read Timing

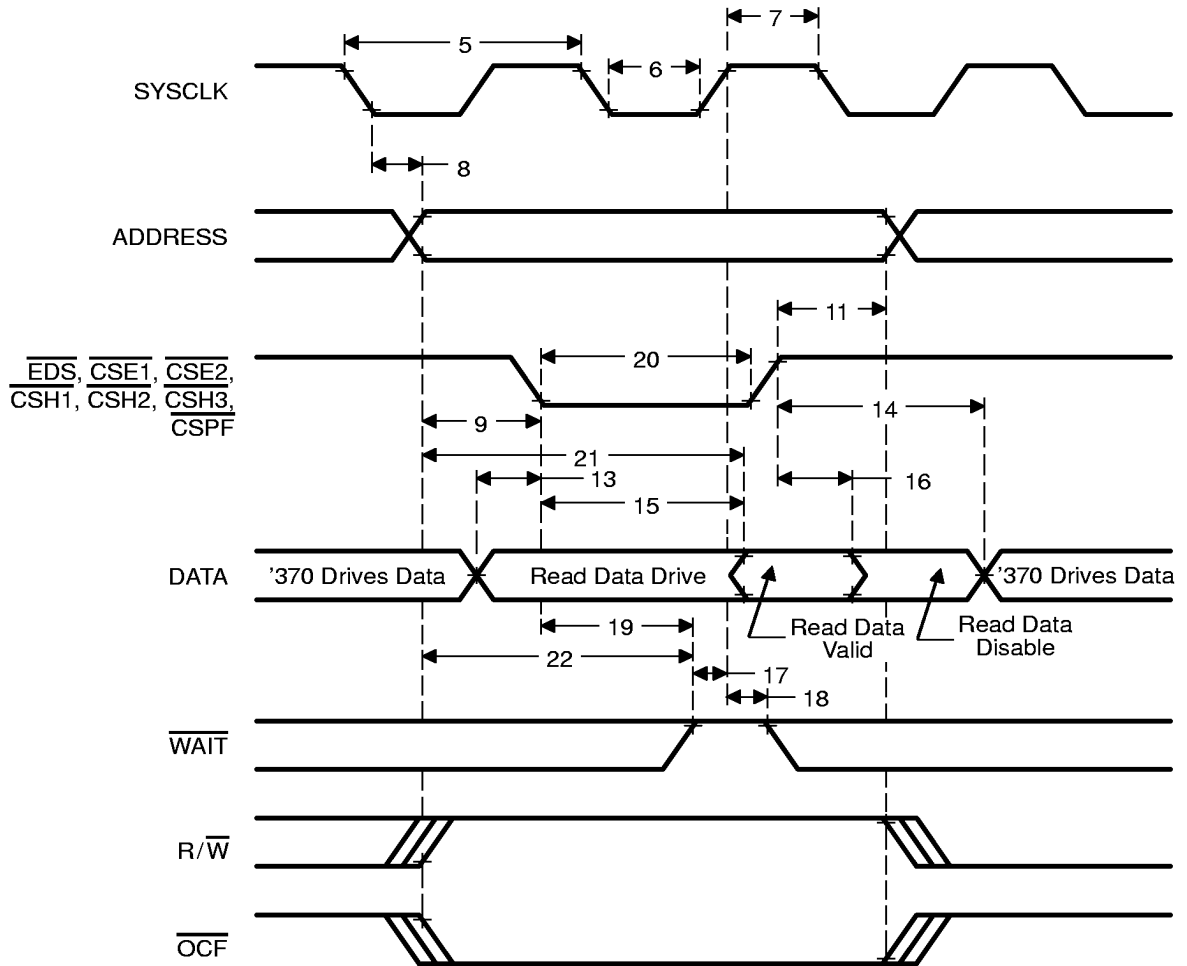
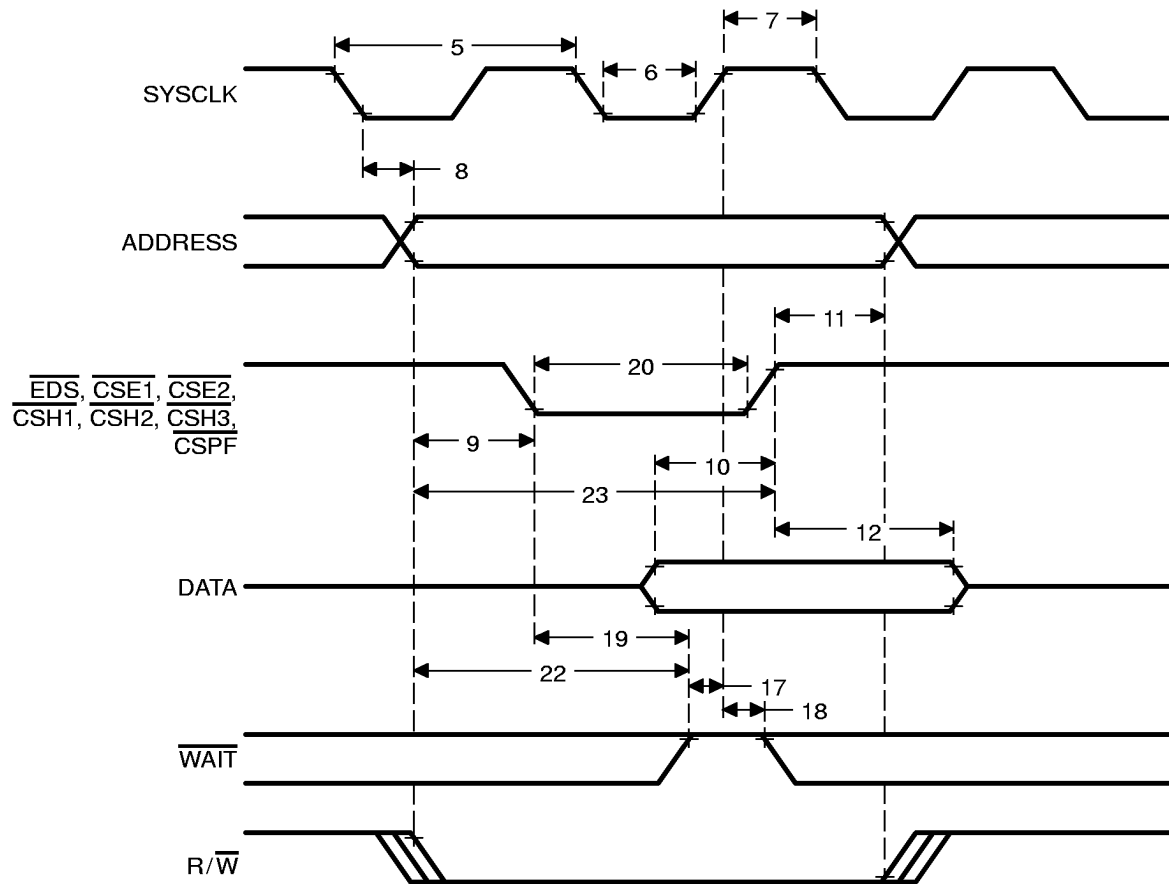


Figure 18–27. External Write Timing



18.14 TMS370Cx6xA Specifications

The tables in this section give specifications that apply to the devices in the TMS370Cx6xA category. These devices include the TMS370C067A, TMS370C068A, TMS370C069A, TMS370C768A, TMS370C769A, SE370C768A, and SE370C769A.

18.14.1 TMS370Cx6xA Electrical Specifications

Stresses beyond those listed in Table 18–1 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the recommended operating conditions in Table 18–41 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



Table 18–41. Recommended Operating Conditions (See Note 1)

| Parameter | | Min | Nom | Max | Unit | |
|------------------|--|--|-----------------------|-----------------------|-----------------------|---|
| V _{CC1} | Supply voltage | 4.5 | 5 | 5.5 | V | |
| | RAM data-retention supply voltage (see Note 2) | 3 | | 5.5 | V | |
| V _{CC2} | Digital I/O supply voltage | 4.5 | 5 | 5.5 | V | |
| V _{CC3} | Analog supply voltage | 4.5 | 5 | 5.5 | V | |
| V _{SS2} | Digital I/O supply ground | –0.3 | 0 | 0.3 | V | |
| V _{SS3} | Analog supply ground | –0.3 | 0 | 0.3 | V | |
| V _{IL} | Low-level input voltage | All pins except MC | V _{SS1} | 0.8 | V | |
| | | MC, normal operation | V _{SS1} | 0.3 | V | |
| V _{IH} | High-level input voltage | All pins except MC, XTAL2/CLKIN, and $\overline{\text{RESET}}$ | 2 | V _{CC1} | V | |
| | | MC (non-WPO mode) | V _{CC1} –0.3 | V _{CC1} +0.3 | V | |
| | | XTAL2/CLKIN | 0.8V _{CC1} | V _{CC1} | V | |
| | | $\overline{\text{RESET}}$ | 0.7V _{CC1} | V _{CC1} | V | |
| V _{MC} | MC (mode control) voltage (see Note 3) | EEPROM write-protect override (WPO) mode | 11.7 | 12 | 13 | V |
| | | EPROM programming voltage (V _{PP}) | 13 | 13.2 | 13.5 | V |
| | | Microprocessor mode | V _{CC1} –0.3 | | V _{CC1} +0.3 | V |
| | | Microcomputer mode | V _{SS1} | | 0.3 | V |
| T _A | Operating free-air temperature | L version | 0 | 70 | °C | |
| | | A version | –40 | 85 | °C | |
| | | T version | –40 | 105 | °C | |

- Notes:**
- 1) Unless otherwise noted, all voltage values are with respect to V_{SS1}.
 - 2) $\overline{\text{RESET}}$ must be externally activated when V_{CC1} or SYSCLK is out of the recommended operating range.
 - 3) The basic microcomputer and microprocessor operating modes are selected by the voltage level applied to the dedicated MC pin two system-clock cycles (2t_C) before $\overline{\text{RESET}}$ goes inactive (high). The WPO mode can be selected any time a sufficient voltage is present on MC.

You cannot use the internal connections between pins (for example, the connection between V_{SS1} and V_{SS2}) for a jumper from one side of the chip to the other.



Table 18–42. Electrical Characteristics Over Recommended Operating Free-Air Temperature Range

| Parameter | | Test Conditions | Min | Typ | Max | Unit | |
|-----------|--|---|---|-----|-----|---------------|---------------|
| V_{OL} | Low-level output voltage | $I_{OL} = 1.4 \text{ mA}$ | | | 0.4 | V | |
| V_{OH} | High-level output voltage | $I_{OH} = -50 \text{ } \mu\text{A}$ | $0.9V_{CC1}$ | | | V | |
| | | $I_{OH} = -2 \text{ mA}$ | 2.4 | | | V | |
| I_I | Input current | MC | $0 \text{ V} < V_I \leq 0.3 \text{ V}$ | | | 10 | μA |
| | | | $0.3 \text{ V} < V_I < V_{CC1} - 0.3 \text{ V}$ | | | 50 | μA |
| | | | $V_{CC1} - 0.3 \text{ V} \leq V_I \leq V_{CC1} + 0.3 \text{ V}$ | | | 10 | μA |
| | | | $V_{CC1} + 0.3 \text{ V} < V_I \leq 13 \text{ V}$ | | | 650 | μA |
| | | $12 \text{ V} \leq V_I \leq 13 \text{ V}$ (see Note 1) | | | 50 | mA | |
| | I/O pins | $0 \text{ V} \leq V_I \leq V_{CC1}$ | | | | ± 10 | μA |
| I_{OL} | Low-level output current | $V_{OL} = 0.4 \text{ V}$ | 1.4 | | | mA | |
| I_{OH} | High-level output current | $V_{OH} = 0.9V_{CC1}$ | -50 | | | μA | |
| | | $V_{OH} = 2.4 \text{ V}$ | -2 | | | mA | |
| I_{CC1} | Supply current (operating mode) OSC POWER bit = 0 (see Note 4) | 'Cx67A, 'Cx68A | See Notes 2 and 3 SYSCLK = 5 MHz | | 35 | 56 | mA |
| | | 'Cx67A, 'Cx68A | See Notes 2 and 3 SYSCLK = 3 MHz | | 25 | 36 | mA |
| | | 'Cx69A† | See Notes 2 and 3 SYSCLK = 3 MHz | | 46 | 55 | mA |
| | | 'Cx67A, 'Cx68A | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 13 | 18 | mA |
| | 'Cx69A† | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 22 | 28 | mA | |
| I_{CC1} | Supply current (STANDBY mode) OSC POWER bit = 0 (see Note 5) | See Notes 2 and 3 SYSCLK = 5 MHz | | 12 | 17 | mA | |
| | | See Notes 2 and 3 SYSCLK = 3 MHz | | 8 | 11 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 2.5 | 3.5 | mA | |
| I_{CC1} | Supply current (STANDBY mode) OSC POWER bit = 1 (see Note 6) | See Notes 2 and 3 SYSCLK = 3 MHz | | 6 | 8.6 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 2 | 3 | mA | |
| I_{CC1} | Supply current (HALT mode) | See Note 2 XTAL2/CLKIN < 0.2 V | | 2 | 30 | μA | |

† TMS370Cx69A operates only up to 3 MHz SYSCLK.

- Notes:**
- 1) Input current I_{pp} is a maximum of 50 mA only when EPROM is being programmed.
 - 2) Single-chip mode, ports configured as inputs or as outputs with no load. All inputs $\leq 0.2 \text{ V}$ or $\geq V_{CC1} - 0.2 \text{ V}$.
 - 3) XTAL2/CLKIN is driven with an external square wave signal with 50% duty cycle and rise and fall times less than 10 ns. Current can be higher with a crystal oscillator. At 5-MHz SYSCLK, this extra current = $0.01 \text{ mA} \times (\text{total load capacitance} + \text{crystal capacitance in pF})$.
 - 4) Maximum operating current = $10(\text{SYSCLK}) + 5.8 \text{ mA}$.
 - 5) Maximum standby current = $3(\text{SYSCLK}) + 2 \text{ mA}$ (OSC POWER bit = 0).
 - 6) Maximum standby current = $2.24(\text{SYSCLK}) + 1.9 \text{ mA}$ (OSC POWER bit = 1; valid only up to 3-MHz SYSCLK).

18.14.2 TMS370Cx6xA Timings

Refer to Sections 18.1 and 18.2 (both on page 18-2) for timing symbol definitions and parameter measurement points.

Table 18–43. External Clocking Requirements for Divide-by-4 Clock (see Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|--|-----|-----|------|
| 1 | $t_{w(Cl)}$ Pulse duration, XTAL2/CLKIN (see Note 2) | 20 | | ns |
| 2 | $t_{r(Cl)}$ Rise time, XTAL2/CLKIN | | 30 | ns |
| 3 | $t_{f(Cl)}$ Fall time, XTAL2/CLKIN | | 30 | ns |
| 4 | $t_{d(CIH-SCL)}$ Delay time, XTAL2/CLKIN rise to SYSCLK fall | | 100 | ns |
| | CLKIN Crystal operating frequency (see note 3) | 2 | 20 | MHz |
| | SYSCLK Internal system clock operating frequency (see Notes 4 and 5) | 0.5 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions table in Table 18–41.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–28, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle, or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) TMS370Cx69A operates up to 12 MHz CLKIN.
 - 4) TMS370Cx69A operates up to 3 MHz SYSCLK.
 - 5) SYSCLK = CLKIN/4

Figure 18–28. External Clock Timing for Divide-by-4 Clock

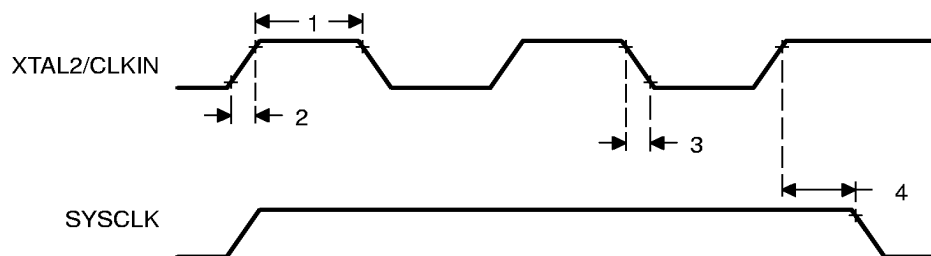


Table 18–44. External Clocking Requirements for Divide-by-1 Clock (PLL)(See Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|------------------|-----|-----|------|
| 1 | $t_{w(CI)}$ | 20 | | ns |
| 2 | $t_{r(CI)}$ | | 30 | ns |
| 3 | $t_{f(CI)}$ | | 30 | ns |
| 4 | $t_{d(CIH-SCH)}$ | | 100 | ns |
| | CLKIN | 2 | 5 | MHz |
| | SYSCLK | 2 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–41.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–29, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle, or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) TMS370Cx69A operates up to 3-MHz CLKIN (for the divide-by-1 clock option).
 - 4) TMS370Cx69A operates up to 3 MHz SYSCLK.
 - 5) $SYSCLK = CLKIN/1$

Figure 18–29. External Clock Timing for Divide-by-1 Clock

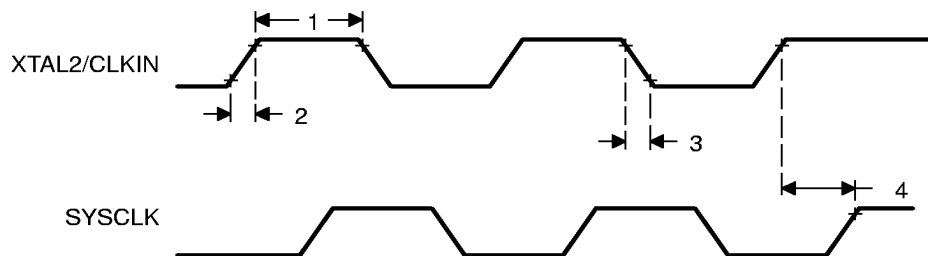


Table 18–45. Switching Characteristics and Timing Requirements for External Read and Write (See Note 1)

| No. | Parameter | | Min | Max | Unit | |
|-----|------------------|--|-------------------------|------------------------------|------------------------------|----|
| 5 | t_c | Cycle time, SYSCLK | Divide-by-4 clock | 200 | 2000 | ns |
| | | | Divide-by-1 clock (PLL) | 200 | 500 | ns |
| 6 | $t_{w(SCL)}$ | Pulse duration, SYSCLK low | | $0.5t_c - 25$ | $0.5t_c$ | ns |
| 7 | $t_{w(SCH)}$ | Pulse duration, SYSCLK high | | $0.5t_c$ | $0.5t_c + 20$ | ns |
| 8 | $t_{d(SCL-A)}$ | Delay time, SYSCLK low to address, R/\overline{W} , and \overline{OCF} valid | | | $0.25t_c + 75$ | ns |
| 9 | $t_{v(A)}$ | Valid time, address valid to \overline{EDS} , $\overline{CSE1}$, $\overline{CSH1}$, and \overline{CSPF} low | | $0.5t_c - 90$ | | ns |
| 10 | $t_{su(D)}$ | Setup time, write data to \overline{EDS} high | | $0.75t_c - 80$ See Note 2 | | ns |
| 11 | $t_{h(EH-A)}$ | Hold time, address, R/\overline{W} , and \overline{OCF} from \overline{EDS} , $\overline{CSE1}$, $\overline{CSH1}$, and \overline{CSPF} high | | $0.5t_c - 60$ | | ns |
| 12 | $t_{h(EH-D)W}$ | Hold time, write data time from \overline{EDS} high | | $0.75t_c + 15$ | | ns |
| 13 | $t_{d(DZ-EL)}$ | Delay time, data bus high impedance to \overline{EDS} low (read cycle) | | $0.25t_c - 35$ | | ns |
| 14 | $t_{d(EH-D)}$ | Delay time, \overline{EDS} high to data bus enable (read cycle) | | $1.25t_c - 40$ | | ns |
| 15 | $t_{d(EL-DV)R}$ | Delay time, \overline{EDS} low to read data valid | | | $t_c - 95$ See Note 2 | ns |
| 16 | $t_{h(EH-D)R}$ | Hold time, read from \overline{EDS} high | | 0 | | ns |
| 17 | $t_{su(WT-SCH)}$ | Setup time, \overline{WAIT} to SYSCLK high | | $0.25t_c + 70$ See Note 3 | | ns |
| 18 | $t_{h(SCH-WT)}$ | Hold time, \overline{WAIT} from SYSCLK high | | 0 | | ns |
| 19 | $t_{d(EL-WTV)}$ | Delay time, \overline{EDS} low to \overline{WAIT} valid | | | $0.5t_c - 60$ | ns |
| 20 | t_w | Pulse duration, \overline{EDS} , $\overline{CSE1}$, $\overline{CSH1}$, and \overline{CSPF} low | | $t_c - 80$ See Note 2 | $t_c + 40$ See Note 2 | ns |
| 21 | $t_{d(AV-DV)R}$ | Delay time, address valid to read data valid | | | $1.5t_c - 115$ See Note 2 | ns |
| 22 | $t_{d(AV-WTV)}$ | Delay time, address valid to \overline{WAIT} valid | | | $t_c - 115$ | ns |
| 23 | $t_{d(AV-EH)}$ | Delay time, address valid to \overline{EDS} high (end of write) | | $1.5t_c - 85$ See Note 2 | | ns |

- Notes:**
- 1) t_c = system clock cycle time = 1/SYSCLK
 - 2) If wait states, PFWait, or the autowait feature is used, add t_c to this value for each wait state invoked.
 - 3) If the autowait feature is enabled, the \overline{WAIT} input can assume a "don't care" condition until the third cycle of the access. The \overline{WAIT} signal must be synchronized with the high pulse of the SYSCLK signal while still conforming to the minimum setup time.



Figure 18–30. External Read Timing

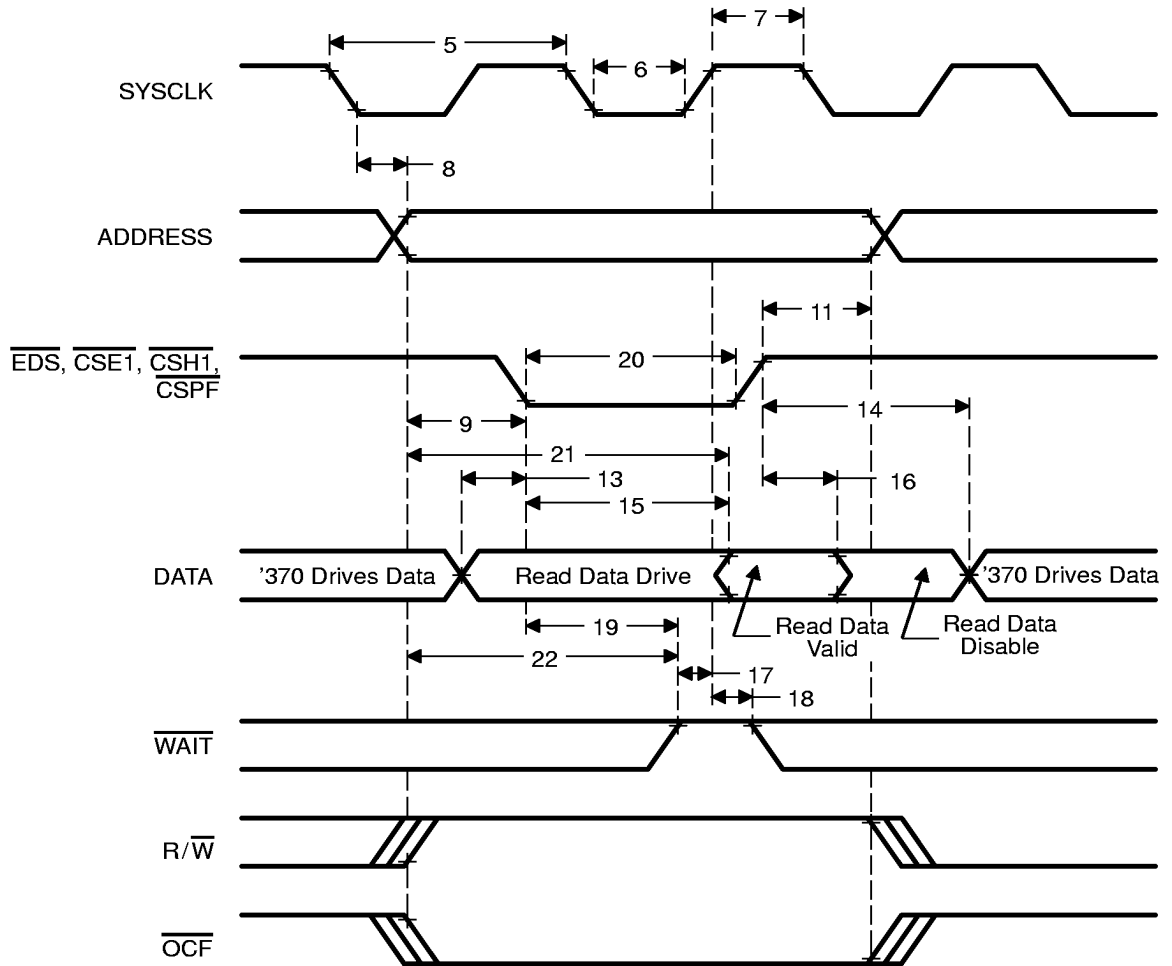
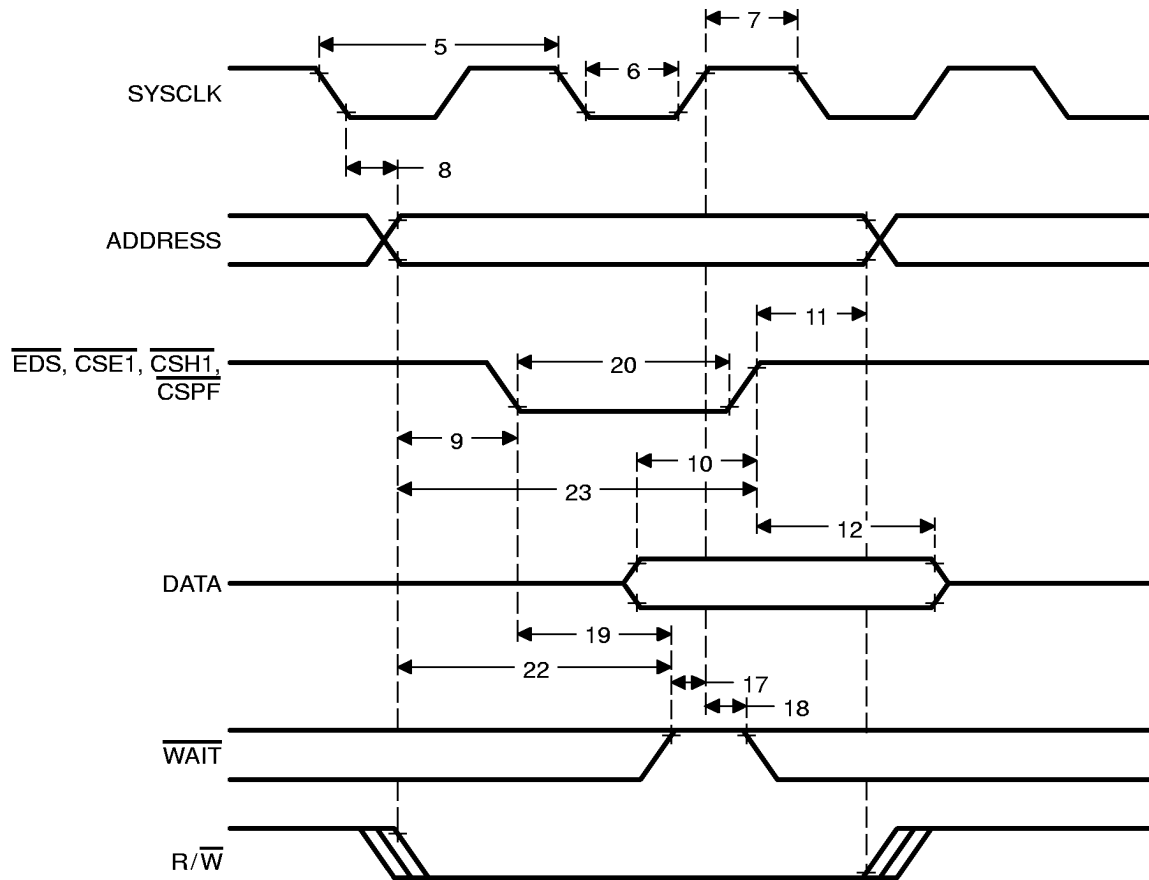


Figure 18–31. External Write Timing



18.15 TMS370Cx7xA Specifications

The tables in this section give specifications that apply to the devices in the TMS370Cx7xA category. These devices include the TMS370C077A, TMS370C777A, and SE370C777A.

18.15.1 TMS370Cx7xA Electrical Specifications

Stresses beyond those listed in Table 18–1 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the recommended operating conditions in Table 18–46 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



Table 18–46. Recommended Operating Conditions (See Note 1)

| Parameter | | Min | Nom | Max | Unit | |
|------------------|--|--|-----------------------|-----------------------|-----------------------|---|
| V _{CC1} | Supply voltage | 4.5 | 5 | 5.5 | V | |
| | RAM data-retention supply voltage (see Note 2) | 3 | | 5.5 | V | |
| V _{CC2} | Digital I/O supply voltage | 4.5 | 5 | 5.5 | V | |
| V _{CC3} | Analog supply voltage | 4.5 | 5 | 5.5 | V | |
| V _{SS2} | Digital I/O supply ground | –0.3 | 0 | 0.3 | V | |
| V _{SS3} | Analog supply ground | –0.3 | 0 | 0.3 | V | |
| V _{IL} | Low-level input voltage | All pins except MC | V _{SS1} | 0.8 | V | |
| | | MC, normal operation | V _{SS1} | 0.3 | V | |
| V _{IH} | High-level input voltage | All pins except MC, XTAL2/CLKIN, and $\overline{\text{RESET}}$ | 2 | V _{CC1} | V | |
| | | MC (non-WPO mode) | V _{CC1} –0.3 | V _{CC1} +0.3 | V | |
| | | XTAL2/CLKIN | 0.8V _{CC1} | V _{CC1} | V | |
| | | $\overline{\text{RESET}}$ | 0.7V _{CC1} | V _{CC1} | V | |
| V _{MC} | MC (mode control) voltage (see Note 3) | EEPROM write-protect override (WPO) mode | 11.7 | 12 | 13 | V |
| | | EPROM programming voltage (V _{PP}) | 13 | 13.2 | 13.5 | V |
| | | Microprocessor mode | V _{CC1} –0.3 | | V _{CC1} +0.3 | V |
| | | Microcomputer mode | V _{SS1} | | 0.3 | V |
| T _A | Operating free-air temperature | L version | 0 | 70 | °C | |
| | | A version | –40 | 85 | °C | |
| | | T version | –40 | 105 | °C | |

- Notes:**
- 1) Unless otherwise noted, all voltage values are with respect to V_{SS1}.
 - 2) $\overline{\text{RESET}}$ must be activated externally when V_{CC1} or SYSCLK is out of the recommended operating range.
 - 3) The basic microcomputer and microprocessor operating modes are selected by the voltage level applied to the dedicated MC pin two system clock cycles (2t_C) before $\overline{\text{RESET}}$ goes inactive (high). The WPO mode can be selected any time a sufficient voltage is present on MC.

You cannot use the internal connections between pins (for example, the connection between V_{SS1} and V_{SS2}) for a jumper from one side of the chip to the other.



Table 18–47. Electrical Characteristics Over Recommended Operating Free-Air Temperature Range

| Parameter | | Test Conditions | Min | Typ | Max | Unit | |
|-----------|---|---|---|-----|----------|---------------|---------------|
| V_{OL} | Low-level output voltage | $I_{OL} = 1.4 \text{ mA}$ | | | 0.4 | V | |
| V_{OH} | High-level output voltage | $I_{OH} = -50 \text{ } \mu\text{A}$ | $0.9V_{CC1}$ | | | V | |
| | | $I_{OH} = -2 \text{ mA}$ | 2.4 | | | | |
| I_I | Input current | MC | $0 \text{ V} < V_I \leq 0.3 \text{ V}$ | | | 10 | μA |
| | | | $0.3 \text{ V} < V_I < V_{CC1} - 0.3 \text{ V}$ | | | 50 | |
| | | | $V_{CC1} - 0.3 \text{ V} \leq V_I \leq V_{CC1} + 0.3 \text{ V}$ | | | 10 | |
| | | | $V_{CC1} + 0.3 \text{ V} < V_I \leq 13 \text{ V}$ | | | 650 | |
| | | $12 \text{ V} \leq V_I \leq 13 \text{ V}$ (see Note 1) | | | 50 | mA | |
| | I/O pins | $0 \text{ V} \leq V_I \leq V_{CC1}$ | | | ± 10 | μA | |
| I_{OL} | Low-level output current | $V_{OL} = 0.4 \text{ V}$ | 1.4 | | | mA | |
| I_{OH} | High-level output current | $V_{OH} = 0.9V_{CC1}$ | -50 | | | μA | |
| | | $V_{OH} = 2.4 \text{ V}$ | -2 | | | mA | |
| I_{CC} | Supply current (operating mode) OSC POWER bit = 0 (see Note 4) | See Notes 2 and 3 SYSCLK = 5 MHz | | 35 | 56 | mA | |
| | | See Notes 2 and 3 SYSCLK = 3 MHz | | 25 | 36 | | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 13 | 18 | | |
| I_{CC} | Supply current (STANDBY mode) OSC POWER bit = 0 (see Note 5) | See Notes 2 and 3 SYSCLK = 5 MHz | | 12 | 17 | mA | |
| | | See Notes 2 and 3 SYSCLK = 3 MHz | | 8 | 11 | | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 2.5 | 3.5 | | |
| I_{CC} | Supply current (STANDBY mode) OSC POWER bit = 1 (see Note 6) | See Notes 2 and 3 SYSCLK = 3 MHz | | 6 | 8.6 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 2 | 3 | | |
| I_{CC} | Supply current (HALT mode) | See Note 2 XTAL2/CLKIN < 0.2 V | | 2 | 30 | μA | |

- Notes:**
- 1) Input current I_{pp} is a maximum of 50 mA only when EPROM is being programmed.
 - 2) Single-chip mode, ports configured as inputs or as outputs with no load. All inputs $\leq 0.2 \text{ V}$ or $\geq V_{CC1} - 0.2 \text{ V}$.
 - 3) XTAL2/CLKIN is driven with an external square wave signal with 50% duty cycle and rise and fall times less than 10 ns. Current can be higher with a crystal oscillator. At 5 MHz SYSCLK, this extra current = $0.01 \text{ mA} \times (\text{total load capacitance} + \text{crystal capacitance in pF})$.
 - 4) Maximum operating current = $10(\text{SYSCLK}) + 5.8 \text{ mA}$.
 - 5) Maximum standby current = $3(\text{SYSCLK}) + 2 \text{ mA}$ (OSC POWER bit = 0).
 - 6) Maximum standby current = $2.24(\text{SYSCLK}) + 1.9 \text{ mA}$ (OSC POWER bit = 1; valid only up to 3-MHz SYSCLK).

18.15.2 TMS370Cx7xA Timings

Refer to Sections 18.1 and 18.2 (page 18-2) for timing symbol definitions and parameter measurement points.

Table 18–48. External Clocking Requirements for Divide-by-4 Clock (See Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|---|-----|-----|------|
| 1 | $t_{w(CI)}$ Pulse duration, XTAL2/CLKIN (see Note 2) | 20 | | ns |
| 2 | $t_{r(CI)}$ Rise time, XTAL2/CLKIN | | 30 | ns |
| 3 | $t_{f(CI)}$ Fall time, XTAL2/CLKIN | | 30 | ns |
| 4 | $t_{d(CIH-SCL)}$ Delay time, XTAL2/CLKIN rise to SYSCLK fall | | 100 | ns |
| | CLKIN Crystal operating frequency | 2 | 20 | MHz |
| | SYSCLK Internal system clock operating frequency (see Note 3) | 0.5 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–46.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–32, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle, or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/4$

Figure 18–32. External Clock Timing for Divide-by-4 Clock

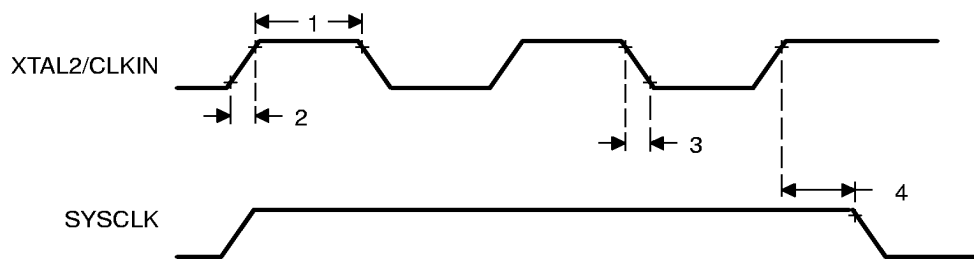


Table 18–49. External Clocking Requirements for Divide-by-1 Clock (PLL)(see Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|------------------|-----|-----|------|
| 1 | $t_{w(CI)}$ | 20 | | ns |
| 2 | $t_{r(CI)}$ | | 30 | ns |
| 3 | $t_{f(CI)}$ | | 30 | ns |
| 4 | $t_{d(CIH-SCH)}$ | | 100 | ns |
| | CLKIN | 2 | 5 | MHz |
| | SYSCLK | 2 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–46.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–33, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle, or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/1$

Figure 18–33. External Clock Timing for Divide-by-1 Clock

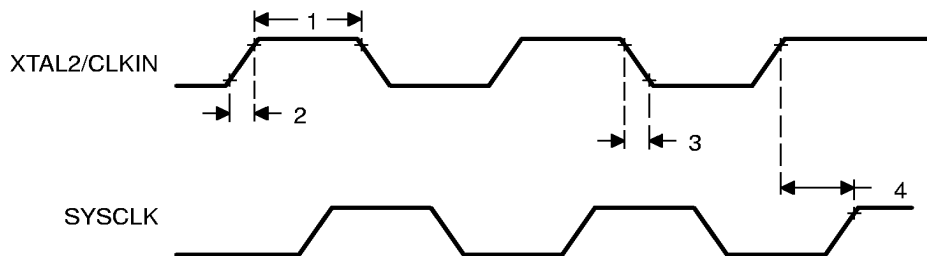
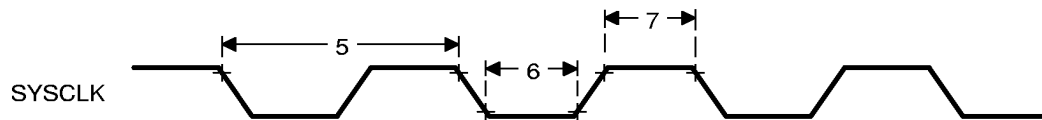


Table 18–50. Switching Characteristics and Timing Requirements (See Note)

| No. | Parameter | | Min | Max | Unit | |
|-----|--------------|-----------------------------|-------------------------|---------------|------|----|
| 5 | t_c | Cycle time, SYSCLK | Divide-by-4 clock | 200 | 2000 | ns |
| | | | Divide-by-1 clock (PLL) | 200 | 500 | ns |
| 6 | $t_{w(SCL)}$ | Pulse duration, SYSCLK low | $0.5t_c - 25$ | $0.5t_c$ | ns | |
| 7 | $t_{w(SCH)}$ | Pulse duration, SYSCLK high | $0.5t_c$ | $0.5t_c + 20$ | ns | |

Note: t_c = system clock cycle time = $1/\text{SYSCLK}$

Figure 18–34. SYSCLK Timing



18.16 TMS370Cx8xA Specifications

The tables in this section give specifications that apply to the devices in the TMS370Cx8xA category. These devices include the TMS370C080A, TMS370C380A, TMS370C686A, and SE370C686A.

18.16.1 TMS370Cx8xA Electrical Specifications

Stresses beyond those listed in Table 18–1 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the recommended operating conditions in Table 18–51 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Table 18–51. Recommended Operating Conditions (See Note 1)

| Parameter | | Min | Nom | Max | Unit | |
|-----------------|--|--|--------------------|-----------------|------|---|
| V _{CC} | Supply voltage | 4.5 | 5 | 5.5 | V | |
| | RAM data-retention supply voltage (see Note 2) | 3 | | 5.5 | V | |
| V _{IL} | Low-level input voltage | All pins except MC | V _{SS} | 0.8 | V | |
| | | MC, normal operation | V _{SS} | 0.3 | V | |
| V _{IH} | High-level input voltage | All pins except MC, XTAL2/CLKIN, and RESET | 2 | V _{CC} | V | |
| | | XTAL2/CLKIN | 0.8V _{CC} | V _{CC} | V | |
| | | RESET | 0.7V _{CC} | V _{CC} | V | |
| V _{MC} | MC (mode control) voltage | EEPROM write-protect override (WPO) mode | 11.7 | 12 | 13 | V |
| | | EPROM programming voltage (V _{PP}) | 13 | 13.2 | 13.5 | V |
| | | Microcomputer mode | V _{SS} | | 0.3 | V |
| T _A | Operating free-air temperature | L version | 0 | 70 | °C | |
| | | A version | –40 | 85 | °C | |
| | | T version | –40 | 105 | °C | |

- Notes:**
- 1) Unless otherwise noted, all voltage values are with respect to V_{SS} (ground).
 - 2) RESET must be externally activated when V_{CC} or SYSCLK is not within the recommended operating range.

Table 18–52. Electrical Characteristics Over Recommended Operating Free-Air Temperature Range

| Parameter | | Test Conditions | Min | Typ | Max | Unit | |
|-----------------|---|--|--|-----|------|------|----|
| V _{OL} | Low-level output voltage | I _{OL} = 1.4 mA | | | 0.4 | V | |
| V _{OH} | High-level output voltage | I _{OH} = –50 μA | 0.9V _{CC} | | | V | |
| | | I _{OH} = –2 mA | 2.4 | | | V | |
| I _I | Input current | MC | 0 V < V _I ≤ 0.3 V | | | 10 | μA |
| | | | 0.3 V < V _I ≤ 13 V | | | 650 | μA |
| | | | 12 V ≤ V _I ≤ 13 V (see Note 1) | | | 50 | mA |
| | I/O pins | 0 V ≤ V _I ≤ V _{CC} | | | ± 10 | μA | |
| I _{OL} | Low-level output current | V _{OL} = 0.4 V | 1.4 | | | mA | |
| I _{OH} | High-level output current | V _{OH} = 0.9V _{CC} | –50 | | | μA | |
| | | V _{OH} = 2.4 V | –2 | | | mA | |
| I _{CC} | Supply current (operating mode) OSC POWER bit = 0 (see Note 4) | See Notes 2 and 3 SYSCLK = 5 MHz | | 30 | 45 | mA | |
| | | See Notes 2 and 3 SYSCLK = 3 MHz | | 20 | 30 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 7 | 11 | mA | |
| I _{CC} | Supply current (STANDBY mode) OSC POWER bit = 0 (see Note 5) | See Notes 2 and 3 SYSCLK = 5 MHz | | 10 | 17 | mA | |
| | | See Notes 2 and 3 SYSCLK = 3 MHz | | 8 | 11 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 2 | 3.5 | mA | |
| I _{CC} | Supply current (STANDBY mode) OSC POWER bit = 1 (see Note 6) | See Notes 2 and 3 SYSCLK = 3 MHz | | 6 | 8.6 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 2 | 3.0 | mA | |
| I _{CC} | Supply current (HALT mode) | See Note 2 XTAL2/CLKIN < 0.2 V | | 2 | 30 | μA | |

- Notes:**
- 1) Input current I_{pp} is a maximum of 50 mA only when EPROM is being programmed.
 - 2) Single-chip mode, ports configured as inputs or as outputs with no load. All inputs ≤ 0.2 V or ≥ V_{CC} – 0.2 V.
 - 3) XTAL2/CLKIN is driven with an external square wave signal with 50% duty cycle and rise and fall times less than 10 ns. Current can be higher with a crystal oscillator. At 5-MHz SYSCLK, this extra current = 0.01 mA × (total load capacitance + crystal capacitance in pF).
 - 4) Maximum operating current = 7.6(SYSCLK) + 7 mA.
 - 5) Maximum standby current = 3(SYSCLK) + 2 mA (OSC POWER bit = 0).
 - 6) Maximum standby current = 2.24(SYSCLK) + 1.9 mA (OSC POWER bit = 1; valid only up to 3-MHz SYSCLK).



18.16.2 TMS370Cx8xA Timings

Refer to Section 18.1 and Section 18.2 (both on page 18-2) for timing symbol definitions and parameter measurement points.

Table 18–53. External Clocking Requirements for Divide-by-4 Clock (See Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|------------------|-----|-----|------|
| 1 | $t_{w(CI)}$ | 20 | | ns |
| 2 | $t_{r(CI)}$ | | 30 | ns |
| 3 | $t_{f(CI)}$ | | 30 | ns |
| 4 | $t_{d(CIH-SCL)}$ | | 100 | ns |
| | CLKIN | 2 | 20 | MHz |
| | SYSCLK | 0.5 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–51.
 - 2) This pulse may be either a high pulse, as illustrated in Figure 18–35, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/4$

Figure 18–35. External Clock Timing for Divide-by-4 Clock

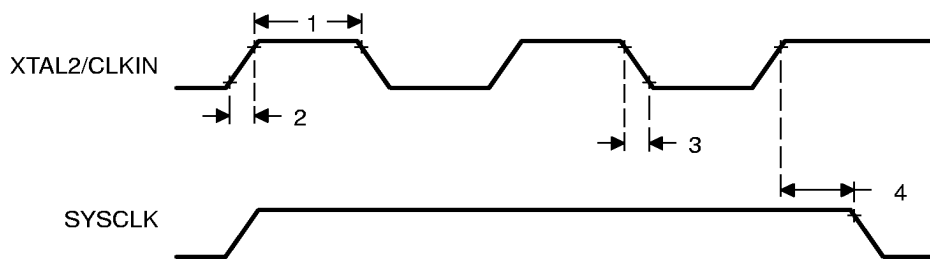


Table 18–54. External Clocking Requirements for Divide-by-1 Clock (PLL) (See Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|------------------|-----|-----|------|
| 1 | $t_{w(CI)}$ | 20 | | ns |
| 2 | $t_{r(CI)}$ | | 30 | ns |
| 3 | $t_{f(CI)}$ | | 30 | ns |
| 4 | $t_{d(CIH-SCH)}$ | | 100 | ns |
| | CLKIN | 2 | 5 | MHz |
| | SYSCLOCK | 2 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–51.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–36, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLOCK = CLKIN/1$

Figure 18–36. External Clock Timing for Divide-by-1 Clock

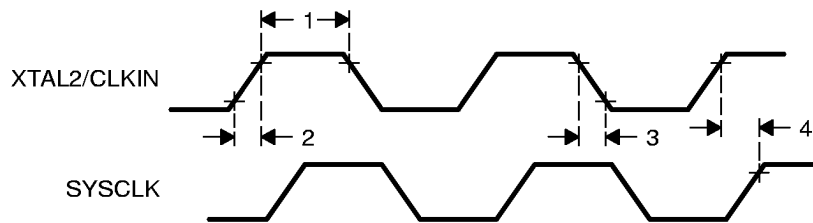
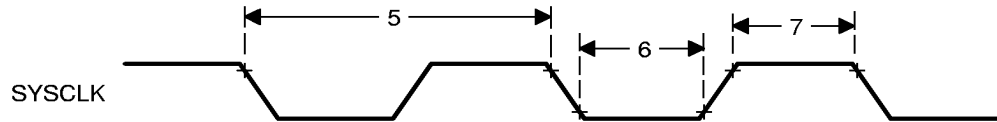


Table 18–55. Switching Characteristics and Timing Requirements (See Note)

| No. | Parameter | | Min | Max | Unit | |
|-----|--------------|-----------------------------|-------------------|---------------|------|----|
| 5 | t_c | Cycle time, SYSCLK | Divide-by-4 clock | 200 | 2000 | ns |
| | | | Divide-by-1 clock | 200 | 500 | ns |
| 6 | $t_{w(SCL)}$ | Pulse duration, SYSCLK low | $0.5t_c - 20$ | $0.5t_c$ | ns | |
| 7 | $t_{w(SCH)}$ | Pulse duration, SYSCLK high | $0.5t_c$ | $0.5t_c + 20$ | ns | |

Note: t_c = system-clock cycle time = $1/\text{SYSCLK}$

Figure 18–37. SYSCLK Timing



18.17 TMS370Cx9xA Specifications

The tables in this section give specifications that apply to the devices in the TMS370Cx9xA category. These devices include the TMS370C090A, TMS370C792A, and SE370C792A.

18.17.1 TMS370Cx9xA Electrical Specifications

Stresses beyond those listed in Table 18–1 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the recommended operating conditions in Table 18–56 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



Table 18–56. Recommended Operating Conditions (See Note 1)

| Parameter | | Min | Nom | Max | Unit | |
|------------------|--|--|--------------------|-----------------|------|---|
| V _{CC} | Supply voltage | 4.5 | 5 | 5.5 | V | |
| | RAM data-retention supply voltage (see Note 2) | 3 | | 5.5 | V | |
| V _{CC3} | Analog supply voltage | 3 | | 5.5 | V | |
| V _{SS3} | Analog supply ground | –0.3 | 0 | 0.3 | V | |
| V _{IL} | Low-level input voltage | All pins except MC | V _{SS} | 0.8 | V | |
| | | MC, normal operation | V _{SS} | 0.3 | V | |
| V _{IH} | High-level input voltage | All pins except MC, XTAL2/CLKIN, and $\overline{\text{RESET}}$ | 2 | V _{CC} | V | |
| | | XTAL2/CLKIN | 0.8V _{CC} | V _{CC} | V | |
| | | $\overline{\text{RESET}}$ | 0.7V _{CC} | V _{CC} | V | |
| V _{MC} | MC (mode control) voltage | EEPROM write-protect override (WPO) mode | 11.7 | 12 | 13 | V |
| | | EPROM programming voltage (V _{PP}) | 13 | 13.2 | 13.5 | V |
| | | Microcomputer mode | V _{SS} | | 0.3 | V |
| T _A | Operating free-air temperature | L version | 0 | 70 | °C | |
| | | A version | –40 | 85 | °C | |
| | | T version | –40 | 105 | °C | |

- Notes:**
- 1) Unless otherwise noted, all voltage values are with respect to V_{SS} (ground).
 - 2) $\overline{\text{RESET}}$ must be externally activated when V_{CC} or SYSCLK is out of the recommended operating range.



Table 18–57. Electrical Characteristics Over Recommended Operating Free-Air Temperature Range

| Parameter | | Test Conditions | Min | Typ | Max | Unit | |
|-----------|--|---------------------------------------|---|-----|----------|---------------|---------------|
| V_{OL} | Low-level output voltage | $I_{OL} = 1.4 \text{ mA}$ | | | 0.4 | V | |
| V_{OH} | High-level output voltage | $I_{OH} = -50 \mu\text{A}$ | $0.9V_{CC}$ | | | V | |
| | | $I_{OH} = -2 \text{ mA}$ | 2.4 | | | V | |
| I_I | Input current | MC | $0 \text{ V} < V_I \leq 0.3 \text{ V}$ | | | 10 | μA |
| | | | $0.3 \text{ V} < V_I \leq 13 \text{ V}$ | | | 650 | μA |
| | | | $12 \text{ V} \leq V_I \leq 13 \text{ V}$ (see Note 1) | | | 50 | mA |
| | I/O pins | $0 \text{ V} \leq V_I \leq V_{CC}$ | | | ± 10 | μA | |
| I_{OL} | Low-level output current | $V_{OL} = 0.4 \text{ V}$ | 1.4 | | | mA | |
| I_{OH} | High-level output current | $V_{OH} = 0.9V_{CC}$ | -50 | | | μA | |
| | | $V_{OH} = 2.4 \text{ V}$ | -2 | | | mA | |
| I_{CC} | Supply current (operating mode) OSC POWER bit = 0 (see Note 4) | See Notes 2 and 3 SYSCLK = 5 MHz | | 30 | 45 | mA | |
| | | See Notes 2 and 3 SYSCLK = 3 MHz | | 20 | 30 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 7 | 11 | mA | |
| I_{CC} | Supply current (STANDBY mode) OSC POWER bit = 0 (see Note 5) | See Notes 2 and 3 SYSCLK = 5 MHz | | 10 | 17 | mA | |
| | | See Notes 2 and 3 SYSCLK = 3 MHz | | 8 | 11 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 2 | 3.5 | mA | |
| I_{CC} | Supply current (STANDBY mode) OSC POWER bit = 1 (see Note 6) | See Notes 2 and 3 SYSCLK = 3 MHz | | 6 | 8.6 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 2 | 3 | mA | |
| I_{CC} | Supply current (HALT mode) | See Note 2 XTAL2/CLKIN < 0.2 V | | 2 | 30 | μA | |

- Notes:**
- 1) Input current I_{pp} is a maximum of 50 mA only when EPROM is being programmed.
 - 2) Single-chip mode, ports configured as inputs or as outputs with no load. All inputs $\leq 0.2 \text{ V}$ or $\geq V_{CC} - 0.2 \text{ V}$.
 - 3) XTAL2/CLKIN is driven with an external square wave signal with 50% duty cycle and rise and fall times less than 10 ns. Current can be higher with a crystal oscillator. At 5-MHz SYSCLK, this extra current = $0.01 \text{ mA} \times (\text{total load capacitance} + \text{crystal capacitance in pF})$.
 - 4) Maximum operating current = $7.6(\text{SYSCLK}) + 7 \text{ mA}$.
 - 5) Maximum standby current = $3(\text{SYSCLK}) + 2 \text{ mA}$ (OSC POWER bit = 0).
 - 6) Maximum standby current = $2.24(\text{SYSCLK}) + 1.9 \text{ mA}$ (OSC POWER bit = 1; valid only up to 3-MHz SYSCLK).



18.17.2 TMS370Cx9xA Timings

Refer to Section 18.1 and Section 18.2 (both on page 18-2) for timing symbol definitions and parameter measurement points.

Table 18–58. External Clocking Requirements for Divide-by-4 Clock (See Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|------------------|-----|-----|------|
| 1 | $t_{w(CI)}$ | 20 | | ns |
| 2 | $t_{r(CI)}$ | | 30 | ns |
| 3 | $t_{f(CI)}$ | | 30 | ns |
| 4 | $t_{d(CIH-SCL)}$ | | 100 | ns |
| | CLKIN | 2 | 20 | MHz |
| | SYSCLK | 0.5 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–56.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–38, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/4$

Figure 18–38. External Clock Timing for Divide-by-4 Clock

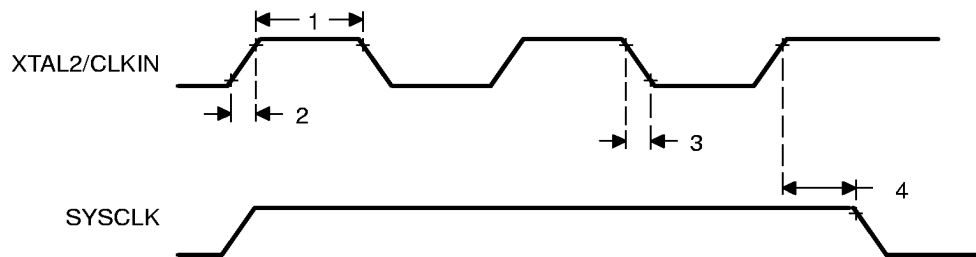


Table 18–59. External Clocking Requirements for Divide-by-1 Clock (PLL) (See Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|------------------|-----|-----|------|
| 1 | $t_{w(CI)}$ | 20 | | ns |
| 2 | $t_{r(CI)}$ | | 30 | ns |
| 3 | $t_{f(CI)}$ | | 30 | ns |
| 4 | $t_{d(CIH-SCH)}$ | | 100 | ns |
| | CLKIN | 2 | 5 | MHz |
| | SYSCLK | 2 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–56.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–39, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/1$

Figure 18–39. External Clock Timing for Divide-by-1 Clock

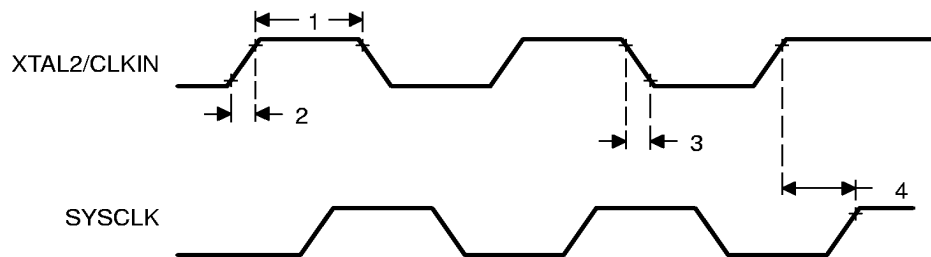
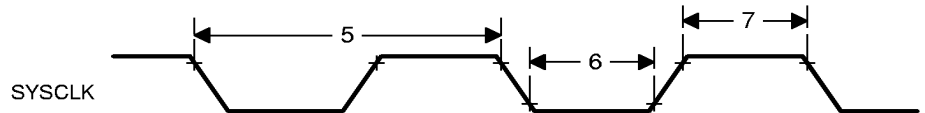


Table 18–60. Switching Characteristics and Timing Requirements (See Note)

| No. | Parameter | Min | Max | Unit | |
|-----|--|-------------------------|---------------|------|----|
| 5 | t_c Cycle time, SYSCLK | Divide-by-4 clock | 200 | 2000 | ns |
| | | Divide-by-1 clock (PLL) | 200 | 500 | ns |
| 6 | $t_{w(SCL)}$ Pulse duration, SYSCLK low | $0.5t_c - 20$ | $0.5t_c$ | ns | |
| 7 | $t_{w(SCH)}$ Pulse duration, SYSCLK high | $0.5t_c$ | $0.5t_c + 20$ | ns | |

Note: t_c = system-clock cycle time = $1/\text{SYSCLK}$

Figure 18–40. SYSCLK Timing



18.18 TMS370CxAxA Specifications

The tables in this section give specifications that apply to the devices in the TMS370CxAxA category. These devices include the TMS370C3A7A.

18.18.1 TMS370CxAxA Electrical Specifications

Stresses beyond those listed in Table 18–1 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the recommended operating conditions in Table 18–61 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Table 18–61. Recommended Operating Conditions (See Note 1)

| Parameter | | | Min | Nom | Max | Unit |
|-----------------|--|--|--------------------|-----|-----------------|------|
| V _{CC} | Supply voltage | | 4.5 | 5 | 5.5 | V |
| | RAM data-retention supply voltage (see Note 2) | | 3 | | 5.5 | V |
| V _{IL} | Low-level input voltage | All pins except MC | V _{SS} | | 0.8 | V |
| | | MC, normal operation | V _{SS} | | 0.3 | V |
| V _{IH} | High-level input voltage | All pins except MC, XTAL2/CLKIN, and $\overline{\text{RESET}}$ | 2 | | V _{CC} | V |
| | | XTAL2/CLKIN | 0.8V _{CC} | | V _{CC} | V |
| | | $\overline{\text{RESET}}$ | 0.7V _{CC} | | V _{CC} | V |
| V _{MC} | MC (mode control) voltage | Microcomputer mode | V _{SS} | | 0.3 | V |
| T _A | Operating free-air temperature | L version | 0 | | 70 | °C |
| | | A version | –40 | | 85 | °C |
| | | T version | –40 | | 105 | °C |

- Notes:**
- 1) Unless otherwise noted, all voltage values are with respect to V_{SS} (ground).
 - 2) $\overline{\text{RESET}}$ must be activated externally when V_{CC} or SYSCLK is out of the recommended operating range.



Table 18–62. Electrical Characteristics Over Recommended Operating Free-Air Temperature Range

| Parameter | | Test Conditions | Min | Typ | Max | Unit | |
|-----------|---|---------------------------------------|---|-----|-----|---------------|---------------|
| V_{OL} | Low-level output voltage | $I_{OL} = 1.4 \text{ mA}$ | | | 0.4 | V | |
| V_{OH} | High-level output voltage | $I_{OH} = -50 \mu\text{A}$ | $0.9V_{CC}$ | | | V | |
| | | $I_{OH} = -2 \text{ mA}$ | 2.4 | | | V | |
| I_I | Input current | MC | $0 \text{ V} < V_I \leq 0.3 \text{ V}$ | | | 10 | μA |
| | | | $0.3 \text{ V} < V_I \leq 13 \text{ V}$ | | | 650 | μA |
| | | I/O pins | $0 \text{ V} \leq V_I \leq V_{CC}$ | | | ± 10 | μA |
| I_{OL} | Low-level output current | $V_{OL} = 0.4 \text{ V}$ | 1.4 | | | mA | |
| I_{OH} | High-level output current | $V_{OH} = 0.9V_{CC}$ | -50 | | | μA | |
| | | $V_{OH} = 2.4 \text{ V}$ | -2 | | | mA | |
| I_{CC} | Supply current (operating mode) OSC POWER bit = 0 (see Note 3) | See Notes 2 and 3 SYSCLK = 5 MHz | | 30 | 45 | mA | |
| | | See Notes 2 and 3 SYSCLK = 3 MHz | | 20 | 30 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 7 | 11 | mA | |
| I_{CC} | Supply current (STANDBY mode) OSC POWER bit = 0 (see Note 4) | See Notes 2 and 3 SYSCLK = 5 MHz | | 10 | 17 | mA | |
| | | See Notes 2 and 3 SYSCLK = 3 MHz | | 8 | 11 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 2 | 3.5 | mA | |
| I_{CC} | Supply current (STANDBY mode) OSC POWER bit = 1 (see Note 5) | See Notes 2 and 3 SYSCLK = 3 MHz | | 6 | 8.6 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 2 | 3.0 | mA | |
| I_{CC} | Supply current (HALT mode) | See Note 1 XTAL2/CLKIN < 0.2 V | | 2 | 30 | μA | |

- Notes:**
- 1) Single-chip mode, ports configured as inputs or as outputs with no load. All inputs $\leq 0.2 \text{ V}$ or $\geq V_{CC} - 0.2 \text{ V}$.
 - 2) XTAL2/CLKIN is driven with an external square wave signal with 50% duty cycle and rise and fall times less than 10 ns. Current can be higher with a crystal oscillator. At 5-MHz SYSCLK, this extra current = $0.01 \text{ mA} \times (\text{total load capacitance} + \text{crystal capacitance in pF})$.
 - 3) Maximum operating current = $7.6(\text{SYSCLK}) + 7 \text{ mA}$.
 - 4) Maximum standby current = $3(\text{SYSCLK}) + 2 \text{ mA}$ (OSC POWER bit = 0).
 - 5) Maximum standby current = $2.24(\text{SYSCLK}) + 1.9 \text{ mA}$ (OSC POWER bit = 1; valid only up to 3-MHz SYSCLK).

18.18.2 TMS370CxAxA Timings

Refer to Section 18.1 and Section 18.2 (both on page 18-2) for timing symbol definitions and parameter measurement points.

Table 18–63. External Clocking Requirements for Divide-by-4 Clock (see Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|---|-----|-----|------|
| 1 | $t_{w(CI)}$ Pulse duration, XTAL2/CLKIN (see Note 2) | 20 | | ns |
| 2 | $t_{r(CI)}$ Rise time, XTAL2/CLKIN | | 30 | ns |
| 3 | $t_{f(CI)}$ Fall time, XTAL2/CLKIN | | 30 | ns |
| 4 | $t_{d(CIH-SCL)}$ Delay time, XTAL2/CLKIN rise to SYSCLK fall | | 100 | ns |
| | CLKIN Crystal operating frequency | 2 | 20 | MHz |
| | SYSCLK Internal system clock operating frequency (see Note 3) | 0.5 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–61.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–41, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle, or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/4$

Figure 18–41. External Clock Timing for Divide-by-4 Clock

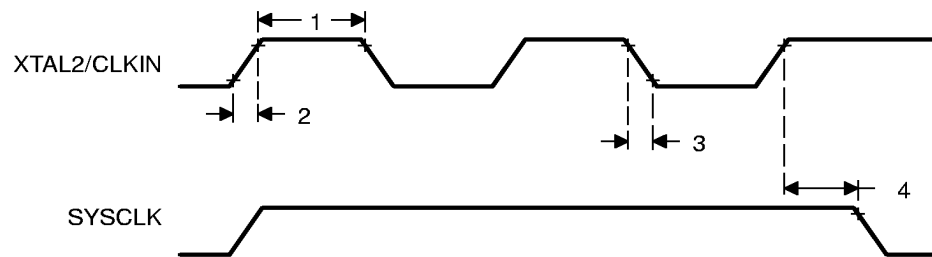


Table 18–64. External Clocking Requirements for Divide-by-1 Clock (PLL) (See Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|----------------|-----|-----|------|
| 1 | $t_{w(CI)}$ | 20 | | ns |
| 2 | $t_r(CI)$ | | 30 | ns |
| 3 | $t_f(CI)$ | | 30 | ns |
| 4 | $t_d(CIH-SCH)$ | | 100 | ns |
| | CLKIN | 2 | 5 | MHz |
| | SYSCLK | 2 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–61.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–42, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle, or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/1$

Figure 18–42. External Clock Timing for Divide-by-1 Clock

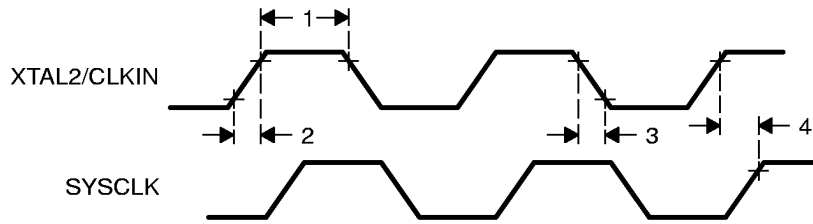
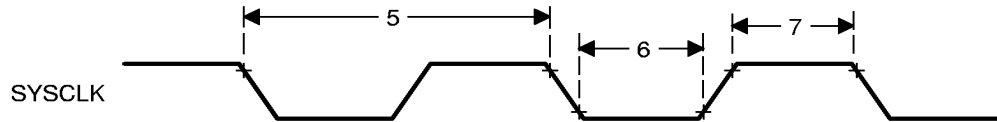


Table 18–65. Switching Characteristics and Timing Requirements (See Note)

| No. | Parameter | | Min | Max | Unit |
|-----|--------------|-----------------------------|---------------|---------------|------|
| 5 | t_c | Cycle time, SYSCLK | | | |
| | | Divide-by-4 clock | 200 | 2000 | ns |
| | | Divide-by-1 clock (PLL) | 200 | 500 | ns |
| 6 | $t_{w(SCL)}$ | Pulse duration, SYSCLK low | $0.5t_c - 20$ | $0.5t_c$ | ns |
| 7 | $t_{w(SCH)}$ | Pulse duration, SYSCLK high | $0.5t_c$ | $0.5t_c + 20$ | ns |

Note: t_c = system-clock cycle time = $1/\text{SYSCLK}$

Figure 18–43. SYSCLK Timing



18.19 TMS370CxBxA Specifications

The tables in this section give specifications that apply to the devices in the TMS370CxBxA category. These devices include the TMS370C0B6A.

18.19.1 TMS370CxBxA Electrical Specifications

Stresses beyond those listed in Table 18–1 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the recommended operating conditions in Table 18–66 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



Table 18–66. Recommended Operating Conditions (See Note 1)

| Parameter | | Min | Nom | Max | Unit | |
|------------------|--|--|------------------------|------------------------|------------------------|----|
| V _{CC1} | Supply voltage | 4.5 | 5 | 5.5 | V | |
| | RAM data-retention supply voltage (see Note 2) | 3 | | 5.5 | V | |
| V _{CC2} | Digital I/O supply voltage | 4.5 | 5 | 5.5 | V | |
| V _{CC3} | Analog supply voltage | 4.5 | 5 | 5.5 | V | |
| V _{SS2} | Digital I/O supply ground | –0.3 | 0 | 0.3 | V | |
| V _{SS3} | Analog supply ground | –0.3 | 0 | 0.3 | V | |
| V _{IL} | Low-level input voltage | All pins except MC | V _{SS1} | 0.8 | V | |
| | | MC, normal operation | V _{SS1} | 0.3 | V | |
| V _{IH} | High-level input voltage | All pins except MC, XTAL2/CLKIN, and RESET | 2 | V _{CC1} | V | |
| | | MC (non-WPO mode) | V _{CC1} – 0.3 | V _{CC1} + 0.3 | V | |
| | | XTAL2/CLKIN | 0.8V _{CC1} | V _{CC1} | V | |
| | | RESET | 0.7V _{CC1} | V _{CC1} | V | |
| V _{MC} | MC (mode control) voltage (see Note 3) | EEPROM write-protect override (WPO) mode | 11.7 | 12 | 13 | V |
| | | Microprocessor mode | V _{CC1} – 0.3 | | V _{CC1} + 0.3 | V |
| | | Microcomputer mode | V _{SS1} | | 0.3 | V |
| T _A | Operating free-air temperature | L version | 0 | | 70 | °C |
| | | A version | –40 | | 85 | °C |
| | | T version | –40 | | 105 | °C |

- Notes:**
- 1) Unless otherwise noted, all voltage values are with respect to V_{SS1}.
 - 2) RESET must be externally activated when V_{CC1} or SYSCLK is out of the recommended operating range.
 - 3) The basic microcomputer and microprocessor operating modes are selected by the voltage level applied to the dedicated MC pin two system clock cycles (2t_C) before RESET goes inactive (high). The WPO mode can be selected any time a sufficient voltage is present on MC.

You cannot use the internal connections between pins (for example, the connection between V_{SS1} and V_{SS2}) for a jumper from one side of the chip to the other.



Table 18–67. Electrical Characteristics Over Recommended Operating Free-Air Temperature Range

| Parameter | | Test Conditions | Min | Typ | Max | Unit | |
|-----------|---|---|---|-----|----------|---------------|---------------|
| V_{OL} | Low-level output voltage | $I_{OL} = 1.4 \text{ mA}$ | | | 0.4 | V | |
| V_{OH} | High-level output voltage | $I_{OH} = -50 \text{ }\mu\text{A}$ | $0.9V_{CC1}$ | | | V | |
| | | $I_{OH} = -2 \text{ mA}$ | 2.4 | | | V | |
| I_I | Input current | MC | $0 \text{ V} < V_I \leq 0.3 \text{ V}$ | | | 10 | μA |
| | | | $0.3 \text{ V} < V_I < V_{CC1} - 0.3 \text{ V}$ | | | 50 | μA |
| | | | $V_{CC1} - 0.3 \text{ V} \leq V_I \leq V_{CC1} + 0.3 \text{ V}$ | | | 10 | μA |
| | | | $V_{CC1} + 0.3 \text{ V} < V_I \leq 13 \text{ V}$ | | | 650 | μA |
| | I/O pins | $0 \text{ V} \leq V_I \leq V_{CC1}$ | | | ± 10 | μA | |
| I_{OL} | Low-level output current | $V_{OL} = 0.4 \text{ V}$ | 1.4 | | | mA | |
| I_{OH} | High-level output current | $V_{OH} = 0.9V_{CC1}$ | -50 | | | μA | |
| | | $V_{OH} = 2.4 \text{ V}$ | -2 | | | mA | |
| I_{CC} | Supply current (operating mode), OSC POWER bit = 0 (see Note 3) | See Notes 1 and 2 SYSCLK = 5 MHz | | 35 | 56 | mA | |
| | | See Notes 1 and 2 SYSCLK = 3 MHz | | 25 | 36 | mA | |
| | | See Notes 1 and 2 SYSCLK = 0.5 MHz | | 13 | 18 | mA | |
| I_{CC} | Supply current (STANDBY mode), OSC POWER bit = 0 (see Note 4) | See Notes 1 and 2 SYSCLK = 5 MHz | | 12 | 17 | mA | |
| | | See Notes 1 and 2 SYSCLK = 3 MHz | | 8 | 11 | mA | |
| | | See Notes 1 and 2 SYSCLK = 0.5 MHz | | 2.5 | 3.5 | mA | |
| I_{CC} | Supply current (STANDBY mode), OSC POWER bit = 1 (see Note 5) | See Notes 1 and 2 SYSCLK = 3 MHz | | 6 | 8.6 | mA | |
| | | See Notes 1 and 2 SYSCLK = 0.5 MHz | | 2 | 3 | mA | |
| I_{CC} | Supply current (HALT mode) | See Note 1 $XTAL2/CLKIN < 0.2 \text{ V}$ | | 2 | 30 | μA | |

- Notes:**
- 1) Single-chip mode, ports configured as inputs or as outputs with no load. All inputs $\leq 0.2 \text{ V}$ or $\geq V_{CC1} - 0.2 \text{ V}$.
 - 2) XTAL2/CLKIN is driven with an external square wave signal with 50% duty cycle and rise and fall times less than 10 ns. Current can be higher with a crystal oscillator. At 5-MHz SYSCLK, this extra current = $0.01 \text{ mA} \times (\text{total load capacitance} + \text{crystal capacitance in pF})$.
 - 3) Maximum operating current = $10(\text{SYSCLK}) + 5.8 \text{ mA}$.
 - 4) Maximum standby current = $3(\text{SYSCLK}) + 2 \text{ mA}$ (OSC POWER bit = 0).
 - 5) Maximum standby current = $2.24(\text{SYSCLK}) + 1.9 \text{ mA}$ (OSC POWER bit = 1; valid only up to 3-MHz SYSCLK).

18.19.2 TMS370CxBxA Timings

Refer to Sections 18.1 and 18.2 (both on page 18-2) for timing symbol definitions and parameter measurement information.

Table 18–68. External Clocking Requirements for Divide-by-4 Clock (See Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|---|-----|-----|------|
| 1 | $t_{w(Cl)}$ Pulse duration, XTAL2/CLKIN (see Note 2) | 20 | | ns |
| 2 | $t_{r(Cl)}$ Rise time, XTAL2/CLKIN | | 30 | ns |
| 3 | $t_{f(Cl)}$ Fall time, XTAL2/CLKIN | | 30 | ns |
| 4 | $t_{d(ClH-SCL)}$ Delay time, XTAL2/CLKIN rise to SYSCLK fall | | 100 | ns |
| | CLKIN Crystal operating frequency | 2 | 20 | MHz |
| | SYSCLK Internal system clock operating frequency (see Note 3) | 0.5 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–66.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–44, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle, or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/4$

Figure 18–44. External Clock Timing for Divide-by-4 Clock

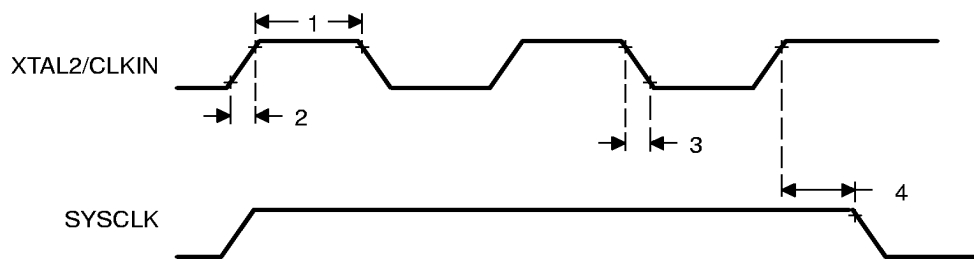


Table 18–69. External Clocking Requirements for Divide-by-1 Clock (PLL) (See Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|------------------|-----|-----|------|
| 1 | $t_{w(CI)}$ | 20 | | ns |
| 2 | $t_{r(CI)}$ | | 30 | ns |
| 3 | $t_{f(CI)}$ | | 30 | ns |
| 4 | $t_{d(CIH-SCH)}$ | | 100 | ns |
| | CLKIN | 2 | 5 | MHz |
| | SYSCLK | 2 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–66.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–45, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle, or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/1$

Figure 18–45. External Clock Timing for Divide-by-1 Clock

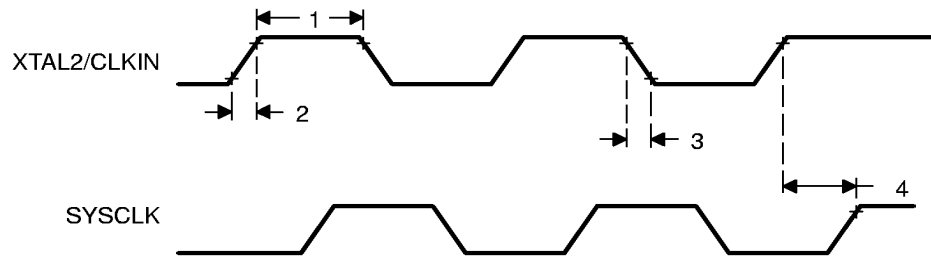
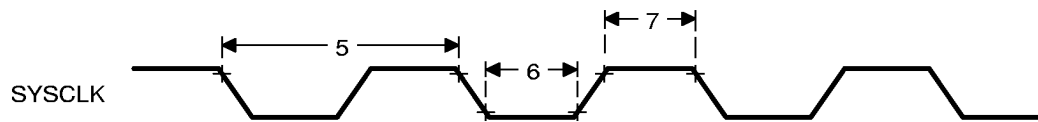


Table 18–70. Switching Characteristics and Timing Requirements (See Note)

| No. | Parameter | | Min | Max | Unit |
|-----|--------------|-----------------------------|---------------|---------------|------|
| 5 | t_c | Cycle time, SYSCLK | | | |
| | | Divide-by-4 clock | 200 | 2000 | ns |
| | | Divide-by-1 clock (PLL) | 200 | 500 | ns |
| 6 | $t_{w(SCL)}$ | Pulse duration, SYSCLK low | $0.5t_c - 25$ | $0.5t_c$ | ns |
| 7 | $t_{w(SCH)}$ | Pulse duration, SYSCLK high | $0.5t_c$ | $0.5t_c + 20$ | ns |

Note: t_c = system clock cycle time = 1/SYSCLK

Figure 18–46. SYSCLK Timing



18.20 TMS370CxCxA Specifications

The tables in this section give specifications that apply to the devices in the TMS370CxCxA category. These devices include the TMS370C3C0A, TMS370C6C2A and SE370C6C2A.

18.20.1 TMS370CxCxA Electrical Specifications

Stresses beyond those listed in Table 18–1 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the recommended operating conditions in Table 18–71 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Table 18–71. Recommended Operating Conditions (See Note 1)

| Parameter | | Min | Nom | Max | Unit | |
|-----------------|--|--|--------------------|-----------------|------|---|
| V _{CC} | Supply voltage | 4.5 | 5 | 5.5 | V | |
| | RAM data-retention supply voltage (see Note 2) | 3 | | 5.5 | V | |
| V _{IL} | Low-level input voltage | All pins except MC | V _{SS} | 0.8 | V | |
| | | MC, normal operation | V _{SS} | 0.3 | V | |
| V _{IH} | High-level input voltage | All pins except MC, XTAL2/CLKIN, and RESET | 2 | V _{CC} | V | |
| | | XTAL2/CLKIN | 0.8V _{CC} | V _{CC} | V | |
| | | $\overline{\text{RESET}}$ | 0.7V _{CC} | V _{CC} | V | |
| V _{MC} | MC (mode control) voltage | EPROM programming voltage (V _{pp}) | 13 | 13.2 | 13.5 | V |
| | | Microcomputer mode | V _{SS} | | 0.3 | V |
| T _A | Operating free-air temperature | L version | 0 | 70 | °C | |
| | | A version | –40 | 85 | °C | |
| | | T version | –40 | 105 | °C | |

- Notes:**
- 1) Unless otherwise noted, all voltage values are with respect to V_{SS} (ground).
 - 2) $\overline{\text{RESET}}$ must be activated externally when V_{CC} or SYSCLK is out of the recommended operating range.

Table 18–72. Electrical Characteristics Over Recommended Operating Free-Air Temperature Range

| Parameter | | Test Conditions | Min | Typ | Max | Unit | |
|-----------|---|---------------------------------------|---|-----|----------|---------------|---------------|
| V_{OL} | Low-level output voltage | $I_{OL} = 1.4 \text{ mA}$ | | | 0.4 | V | |
| V_{OH} | High-level output voltage | $I_{OH} = -50 \text{ } \mu\text{A}$ | $0.9V_{CC}$ | | | V | |
| | | $I_{OH} = -2 \text{ mA}$ | 2.4 | | | V | |
| I_I | Input current | MC | $0 \text{ V} \leq V_I \leq 0.3 \text{ V}$ | | | 10 | μA |
| | | | $0.3 \text{ V} < V_I \leq 13 \text{ V}$ | | | 650 | μA |
| | | | $12 \text{ V} \leq V_I \leq 13 \text{ V}$ (see Note 1) | | | 50 | mA |
| | I/O pins | $0 \text{ V} \leq V_I \leq V_{CC}$ | | | ± 10 | μA | |
| I_{OL} | Low-level output current | $V_{OL} = 0.4 \text{ V}$ | 1.4 | | | mA | |
| I_{OH} | High-level output current | $V_{OH} = 0.9V_{CC}$ | -50 | | | μA | |
| | | $V_{OH} = 2.4 \text{ V}$ | -2 | | | mA | |
| I_{CC} | Supply current (operating mode) OSC POWER bit = 0 (see Note 4) | See Notes 2 and 3 SYSCLK = 5 MHz | | 20 | 36 | mA | |
| | | See Notes 2 and 3 SYSCLK = 3 MHz | | 13 | 25 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 5 | 11 | mA | |
| I_{CC} | Supply current (STANDBY mode) OSC POWER bit = 0 (see Note 5) | See Notes 2 and 3 SYSCLK = 5 MHz | | 10 | 17 | mA | |
| | | See Notes 2 and 3 SYSCLK = 3 MHz | | 6.5 | 11 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 2 | 3.5 | mA | |
| I_{CC} | Supply current (STANDBY mode) OSC POWER bit = 1 (see Note 6) | See Notes 2 and 3 SYSCLK = 3 MHz | | 4.5 | 8.6 | mA | |
| | | See Notes 2 and 3 SYSCLK = 0.5 MHz | | 1.5 | 3.0 | mA | |
| I_{CC} | Supply current (HALT mode) | See Note 2 XTAL2/CLKIN < 0.2 V | | 1 | 30 | μA | |

- Notes:**
- 1) Input current I_{pp} is a maximum of 50 mA only when EPROM is being programmed.
 - 2) Single-chip mode, ports configured as inputs or as outputs with no load. All inputs $\leq 0.2 \text{ V}$ or $\geq V_{CC} - 0.2 \text{ V}$.
 - 3) XTAL2/CLKIN is driven with an external square wave signal with 50% duty cycle and rise and fall times less than 10 ns. Current can be higher with a crystal oscillator. At 5 MHz SYSCLK, this extra current = $0.01 \text{ mA} \times (\text{total load capacitance} + \text{crystal capacitance in pF})$.
 - 4) Maximum operating current = $5.6(\text{SYSCLK}) + 8 \text{ mA}$.
 - 5) Maximum standby current = $3(\text{SYSCLK}) + 2 \text{ mA}$ (OSC POWER bit = 0).
 - 6) Maximum standby current = $2.24(\text{SYSCLK}) + 1.9 \text{ mA}$ (OSC POWER bit = 1; valid only up to 3-MHz SYSCLK).



18.20.2 TMS370CxCA Timings

Refer to Sections 18.1 and 18.2 (both on page 18-2)) for timing symbol definitions and parameter measurement points.

Table 18–73. External Clocking Requirements for Divide-by-4 Clock (See Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|--|-----|-----|------|
| 1 | $t_{w(C)}$ Pulse duration, XTAL2/CLKIN (see Note 2) | 20 | | ns |
| 2 | $t_{r(C)}$ Rise time, XTAL2/CLKIN | | 30 | ns |
| 3 | $t_{f(C)}$ Fall time, XTAL2/CLKIN | | 30 | ns |
| 4 | $t_{d(CIH-SCL)}$ Delay time, XTAL2/CLKIN rise to SYSCLK fall | | 100 | ns |
| | CLKIN | 2 | 20 | MHz |
| | SYSCLK | 0.5 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–71.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–47, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle, or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $SYSCLK = CLKIN/4$

Figure 18–47. External Clock Timing for Divide-by-4 Clock

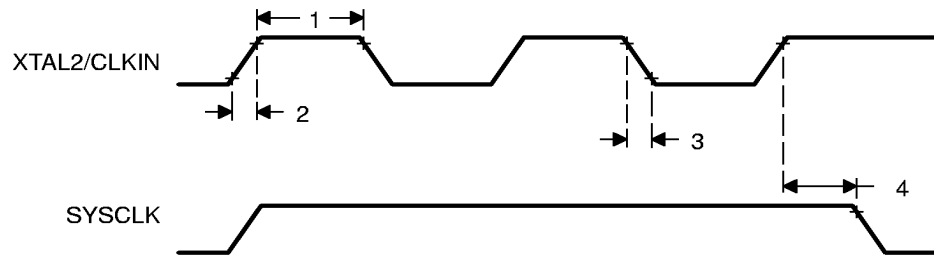


Table 18–74. External Clocking Requirements for Divide-by-1 Clock (PLL) (See Note 1)

| No. | Parameter | Min | Max | Unit |
|-----|-----------------------|-----|-----|------|
| 1 | $t_w(\text{Cl})$ | 20 | | ns |
| 2 | $t_r(\text{Cl})$ | | 30 | ns |
| 3 | $t_f(\text{Cl})$ | | 30 | ns |
| 4 | $t_d(\text{ClH-SCH})$ | | 100 | ns |
| | CLKIN | 2 | 5 | MHz |
| | SYSCLK | 2 | 5 | MHz |

- Notes:**
- 1) For V_{IL} and V_{IH} , refer to recommended operating conditions in Table 18–71.
 - 2) This pulse can be either a high pulse, as illustrated in Figure 18–48, which extends from the earliest valid high to the final valid high in an XTAL2/CLKIN cycle, or a low pulse, which extends from the earliest valid low to the final valid low in an XTAL2/CLKIN cycle.
 - 3) $\text{SYSCLK} = \text{CLKIN}/1$

Figure 18–48. External Clock Timing for Divide-by-1 Clock

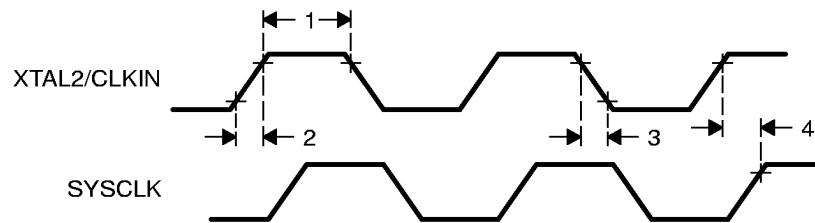
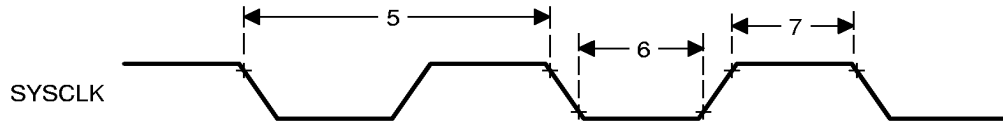


Table 18–75. Switching Characteristics and Timing Requirements (See Note)

| No. | Parameter | | Min | Max | Unit | |
|-----|--------------|-----------------------------|-------------------------|---------------|------|----|
| 5 | t_c | Cycle time, SYSCLK | Divide-by-4 clock | 200 | 2000 | ns |
| | | | Divide-by-1 clock (PLL) | 200 | 500 | ns |
| 6 | $t_{w(SCL)}$ | Pulse duration, SYSCLK low | $0.5t_c - 20$ | $0.5t_c$ | ns | |
| 7 | $t_{w(SCH)}$ | Pulse duration, SYSCLK high | $0.5t_c$ | $0.5t_c + 20$ | ns | |

Note: t_c = system clock cycle time = $1 / \text{SYSCLK}$

Figure 18–49. SYSCLK Timing



18.21 SCI Timings

This section contains timing tables and figures for devices that have the serial communications interface (SCI) module.

Note: Parameter Difference

The $t_{d(SCCL-TXDV)}$ parameter differs for TMS370Cxxx devices. Refer to sub-section A.9.2 on page A-9.

Table 18–76. SCI Isosynchronous Mode Timing Characteristics and Requirements for Internal Clock (See Note)

| No. | Parameter | Min | Max | Unit |
|-----|---|------------------|----------------------|------|
| 24 | $t_{c(SCC)}$ Cycle time, SCICLK | $2t_c$ | $131072t_c$ | ns |
| 25 | $t_w(SCCL)$ Pulse duration, SCICLK low | $t_c - 45$ | $0.5t_{c(SCC)} + 45$ | ns |
| 26 | $t_w(SCCH)$ Pulse duration, SCICLK high | $t_c - 45$ | $0.5t_{c(SCC)} + 45$ | ns |
| 27 | $t_{d(SCCL-TXDV)}$ Delay time, SCITXD valid after SCICLK low | -50 | 60 | ns |
| 28 | $t_{v(SCCH-TXD)}$ Valid time, SCITXD data valid after SCICLK high | $t_w(SCCH) - 50$ | | ns |
| 29 | $t_{su}(RXD-SCCH)$ Setup time, SCIRXD to SCICLK high | $0.25 t_c + 145$ | | ns |
| 30 | $t_{v(SCCH-RXD)}$ Valid time, SCIRXD data valid after SCICLK high | 0 | | ns |

Note: t_c = system clock cycle time = $1 / \text{SYSCLK}$

Figure 18–50. SCI Isosynchronous Mode Timing for Internal Clock

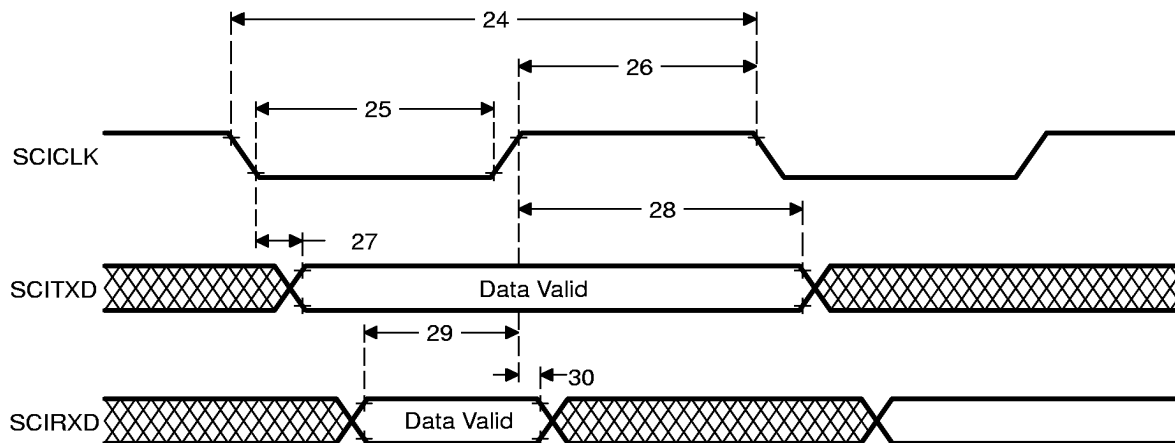
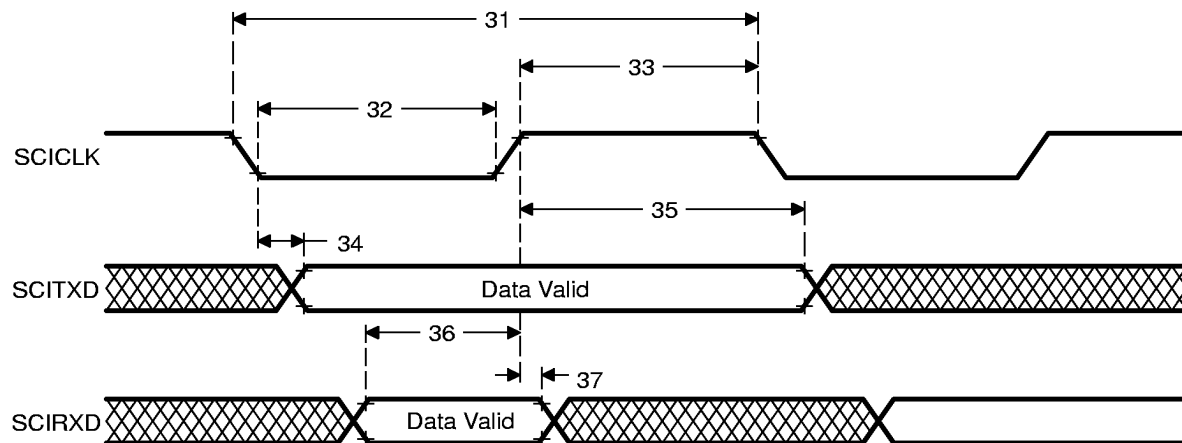


Table 18–77. SCI Isosynchronous Mode Timing Characteristics and Requirements for External Clock (See Note)

| No. | Parameter | Min | Max | Unit |
|-----|---------------------------|---|--------------------|------|
| 31 | $t_c(\text{SCC})$ | Cycle time, SCICLK | $10t_c$ | ns |
| 32 | $t_w(\text{SCCL})$ | Pulse duration, SCICLK low | $4.25t_c + 120$ | ns |
| 33 | $t_w(\text{SCCH})$ | Pulse duration, SCICLK high | $t_c + 120$ | ns |
| 34 | $t_d(\text{SCCL-TXDV})$ | Delay time, SCITXD valid after SCICLK low | $4.25t_c + 145$ | ns |
| 35 | $t_v(\text{SCCH-TXD})$ | Valid time, SCITXD data valid after SCICLK high | $t_w(\text{SCCH})$ | ns |
| 36 | $t_{su}(\text{RXD-SCCH})$ | Setup time, SCIRXD to SCICLK high | 40 | ns |
| 37 | $t_v(\text{SCCH-RXD})$ | Valid time, SCIRXD data after SCICLK high | $2t_c$ | ns |

Note: t_c = system clock cycle time = 1/SYSCLK

Figure 18–51. SCI Isosynchronous Mode Timing for External Clock



18.22 SPI Timings

This section contains timing tables and diagrams for the devices that have the serial peripheral interface (SPI) module in the following categories: TMS370Cx1x, TMS370Cx2x, TMS370Cx36, TMS370Cx5x, and TMS370Cx6x.

Note: Electrical/Timing Specification Differences

Some SPI electrical specifications and timings differ for TMS370Cxxx devices. Refer to subsection A.9.2 on page A-9.

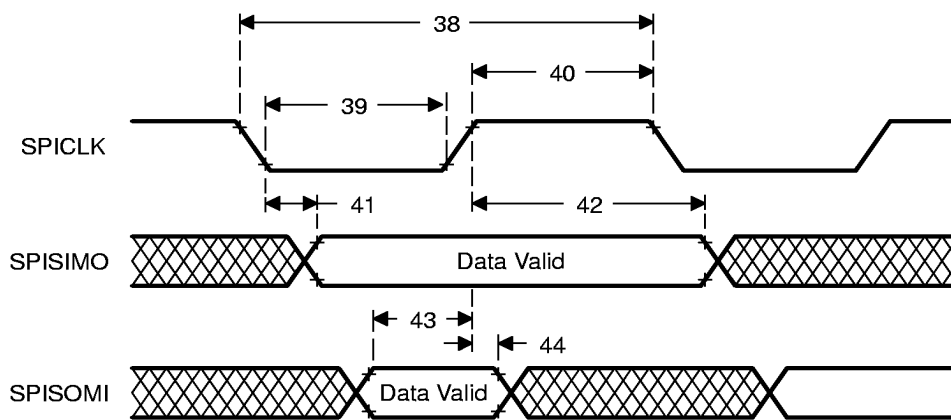
Table 18–78. SPI Master Mode External Timing Characteristics and Requirements
(See Note)

| No. | Parameter | | Min | Max | Unit |
|-----|----------------------|---|--------------------|----------------------|------|
| 38 | $t_{c(SPC)M}$ | Cycle time, SPICLK | $2t_c$ | $256t_c$ | ns |
| 39 | $t_{w(SPCL)M}$ | Pulse duration, SPICLK low | $t_c - 45$ | $0.5t_{c(SPC)} + 45$ | ns |
| 40 | $t_{w(SPCH)M}$ | Pulse duration, SPICLK high | $t_c - 55$ | $0.5t_{c(SPC)} + 45$ | ns |
| 41 | $t_{d(SPCL-SIMOV)M}$ | Delay time, SPISIMO valid after SPICLK low (polarity = 1) | - 65 | 50 | ns |
| 42 | $t_{v(SPCH-SIMO)M}$ | Valid time, SPISIMO after SPICLK high (polarity = 1) | $t_{w(SPCH)} - 50$ | | ns |
| 43 | $t_{su(SOMI-SPCH)M}$ | Setup time, SPISOMI to SPICLK high (polarity = 1) | $0.25 t_c + 150$ | | ns |
| 44 | $t_{v(SPCH-SOMI)M}$ | Valid time, SPISOMI after SPICLK high (polarity = 1) | 0 | | ns |

Note: t_c = system clock cycle time = 1 / SYSCLK



Figure 18–52. SPI Master Mode External Clock Timing



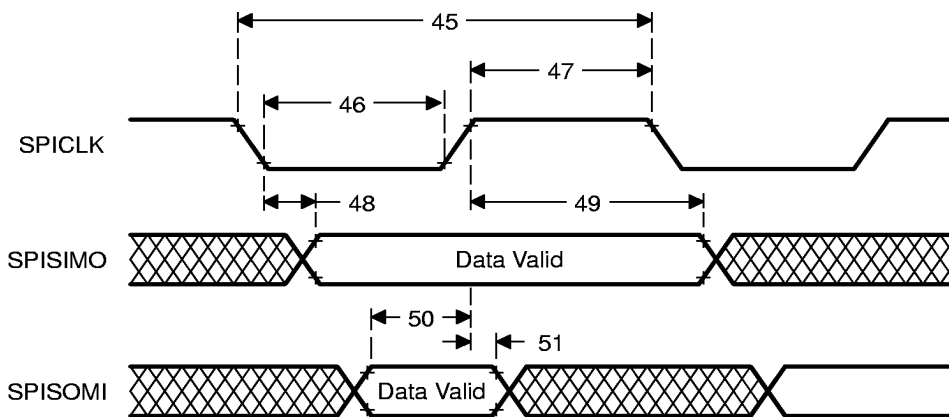
Note: In this figure, polarity = 1. SPICLK is inverted when polarity = 0.

Table 18–79. SPI Slave Mode External Timing Characteristics and Requirements
(See Note)

| No. | | Min | Max | Unit |
|-----|----------------------|----------------|---------------------|------|
| 45 | $t_{c(SPC)S}$ | $8t_c$ | | ns |
| 46 | $t_{w(SPCL)S}$ | $4t_c - 45$ | $0.5t_c(SPC)S + 45$ | ns |
| 47 | $t_{w(SPCH)S}$ | $4t_c - 45$ | $0.5t_c(SPC)S + 45$ | ns |
| 48 | $t_{d(SPCL-SOMIV)S}$ | | $3.25t_c + 130$ | ns |
| 49 | $t_{v(SPCH-SOMI)S}$ | $t_{w(SPCH)S}$ | | ns |
| 50 | $t_{su(SIMO-SPCH)S}$ | 0 | | ns |
| 51 | $t_{v(SPCH-SIMO)S}$ | $3t_c + 100$ | | ns |

Note: t_c = system clock cycle time = 1 / SYSCLK

Figure 18–53. SPI Mode Slave External Timing



- Notes:
- 1) In this figure, polarity = 1. SPICLK is inverted when polarity = 0.
 - 2) As a slave, the SPICLK pin is used as the input for the serial clock, which is supplied from the network master.

18.23 Analog-to-Digital Converter 1 (ADC1) Module Specifications

This section contains specifications for the devices that have the analog-to-digital converter 1 (ADC1) module in the following categories: TMS370Cx32, TMS370Cx36, TMS370Cx4x, TMS370Cx5x, TMS370Cx6x, TMS370Cx7x and TMS370CxBx.

The ADC1 module has a separate power bus for its analog circuitry. These pins are referred to as V_{CC3} and V_{SS3} . The purpose is to enhance ADC1 performance by preventing digital switching noise of the logic circuitry that may be present on V_{SS} and V_{CC} from coupling into the ADC1 analog stage. All ADC1 specifications are given with respect to V_{SS3} unless otherwise noted.

Resolution 8-bits (256 values)
 Monotonic Yes
 Output conversion code 00h to FFh
 (00h for $V_I \leq V_{SS3}$; FFh for $V_I \geq V_{ref}$)
 Conversion time (excluding sample time) $164 t_c$
 (where t_c = system clock cycle time)

Table 18–80. Recommended Operating Conditions

| Parameter | | Min | Nom | Max | Unit |
|-----------|--|----------------|-----------|-----------------|------|
| V_{CC3} | Analog supply voltage | 4.5 | 5 | 5.5 | V |
| | | $V_{CC} - 0.3$ | | $V_{CC} + 0.3$ | V |
| V_{SS3} | Analog ground | $V_{SS} - 0.3$ | | $V_{SS} + 0.3$ | V |
| V_{ref} | Non- V_{CC3} reference (see Note) | 2.5 | V_{CC3} | $V_{CC3} + 0.1$ | V |
| | Analog input for conversion | V_{SS3} | | V_{ref} | V |

Note: V_{ref} must be stable, within $\pm 1/2$ LSB of the required resolution, during the entire conversion time. $V_{CC} = V_{CC1}$ and $V_{SS} = V_{SS1}$ for 'x32, 'x36, 'x5x, 'x6x, 'x7x, and 'xBx devices.



Table 18–81. ADC1 Electrical Characteristics Over Recommended Operating Free-Air Temperature Range

| Parameter | | Test Conditions | Min | Max | Unit |
|-----------|---|---|-----|-----------|------------------|
| | Absolute accuracy (see Note 1) | $V_{CC3} = 5.5\text{ V}$, $V_{ref} = 5.1\text{ V}$ | | ± 1.5 | LSB |
| | Differential/integral linearity error (see Notes 1 and 2) | $V_{CC3} = 5.5\text{ V}$, $V_{ref} = 5.1\text{ V}$ | | ± 0.9 | LSB |
| I_{CC3} | Analog supply current | Converting | | 2 | mA |
| | | Nonconverting | | 5 | μA |
| I_I | Input current, AN0–AN7 | $0\text{ V} \leq V_I \leq 5.5\text{ V}$ | | 2 | μA |
| I_{ref} | input charge current | | | 1 | mA |
| Z_{ref} | Source impedance of V_{ref} | $\text{SYSCLK} \leq 3\text{ MHz}$ | | 24 | $\text{k}\Omega$ |
| | | $3\text{ MHz} < \text{SYSCLK} \leq 5\text{ MHz}$ | | 10 | $\text{k}\Omega$ |

- Notes:**
- 1) Absolute resolution = 20 mV. At $V_{ref} = 5\text{ V}$, this is one LSB. As V_{ref} decreases, LSB size decreases. Therefore, the absolute accuracy and differential/integral linearity errors in terms of LSBs increase.
 - 2) Excluding quantization error of 1/2 LSB

The ADC1 module allows complete freedom in design of the sources for the analog inputs. The period of the sample time is user-defined so that high-impedance sources can be accommodated without penalty to low-impedance sources. The sample period begins when the SAMPLE START bit of the ADC1 control register (ADCTL.6) is set to 1. The end of the signal sample period occurs when the conversion bit (CONVERT START, ADCTL.7) is set to 1. After a hold time, the converter resets the SAMPLE START and CONVERT START bits, signaling that a conversion has started and that the analog signal can be removed.

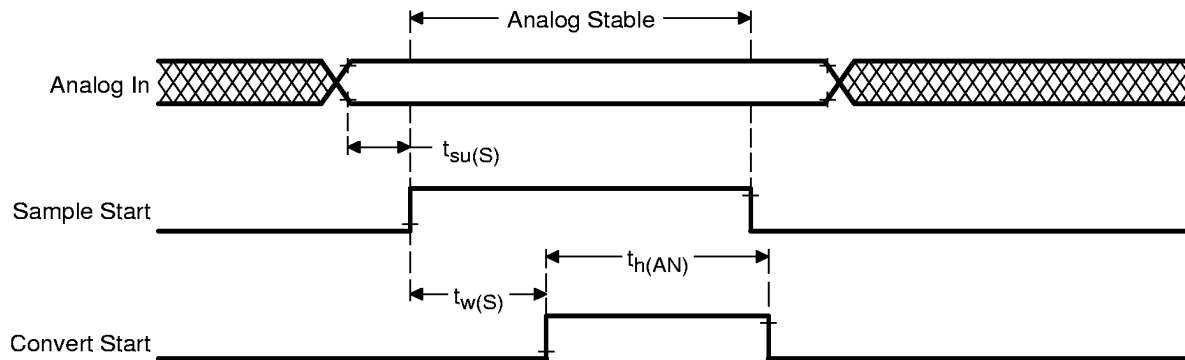


Table 18–82. Analog Timing Requirements

| Parameter | Min | Max | Unit |
|-------------|---------|-----|-----------------|
| $t_{su(S)}$ | 0 | | ns |
| $t_{h(AN)}$ | $18t_c$ | | ns |
| $t_w(S)$ | 1 | | $\mu s/k\Omega$ |

Note: The value given is valid for a signal with a source impedance > 1 k Ω . If the source impedance is < 1 k Ω , use a minimum sampling time of 1 μs .

Figure 18–54. Analog Timing



18.24 Analog-to-Digital Converter 2 (ADC2) Module Specifications

This section contains specifications for the TMS370Cx device category, which has the analog-to-digital converter 2 (ADC2) module. ADC2 shares the V_{CC} power bus for its analog and digital circuitry. All ADC2 specifications are given with respect to V_{SS} unless otherwise noted.

Resolution 8-bits (256 values)
 Monotonic Yes
 Output conversion code 00h to FFh
 (00h for $V_I \leq V_{SS} \leq V_{ref}$; FFh for $V_I \leq V_{ref}$)
 Conversion time (excluding sample time) $164 t_c$
 (where t_c = system clock cycle time)

Table 18–83. Recommended Operating Conditions

| Parameter | | Min | Nom | Max | Unit |
|-----------|------------------------------------|----------|----------|----------------|------|
| V_{CC} | Analog supply voltage | 4.5 | 5 | 5.5 | V |
| V_{ref} | Non- V_{CC} reference (see Note) | 2.5 | V_{CC} | $V_{CC} + 0.1$ | V |
| | Analog input for conversion | V_{SS} | | V_{ref} | V |

Note: V_{ref} must be stable, within $\pm 1/2$ LSB of the required resolution during the entire conversion time.

Table 18–84. ADC2 Electrical Characteristics Over Recommended Operating Free-Air Temperature Range

| Parameter | | Test Conditions | Min | Max | Unit |
|-----------|---|--|-----|-----------|------------------|
| | Absolute accuracy (see Note 1) | $V_{CC} = 5.5 \text{ V}$, $V_{ref} = 5.1 \text{ V}$ | | +1.5 | LSB |
| | Differential/integral linearity error (see Notes 1 and 2) | $V_{CC} = 5.5 \text{ V}$, $V_{ref} = 5.1 \text{ V}$ | | ± 0.9 | LSB |
| I_{CC} | Analog supply current | Converting | | 2 | mA |
| | | Nonconverting | | 5 | μA |
| I_I | Input current, AN0-AN3 | $0 \text{ V} \leq V_I \leq 5.5 \text{ V}$ | | 2 | μA |
| I_{ref} | Input charge current | | | 1 | mA |
| Z_{ref} | Source impedance of V_{ref} | $\text{SYSCLK} \leq 3 \text{ MHz}$ | | 24 | $\text{k}\Omega$ |
| | | $3 \text{ MHz} < \text{SYSCLK} \leq 5 \text{ MHz}$ | | 10 | $\text{k}\Omega$ |

Notes: 1) Absolute resolution = 20 mV. At $V_{ref} = 5 \text{ V}$, this is 1 LSB. As V_{ref} decreases, LSB size decreases and thus absolute accuracy and differential / integral linearity errors in terms of LSBs increases.
 2) Excluding quantization error of 1/2 LSB



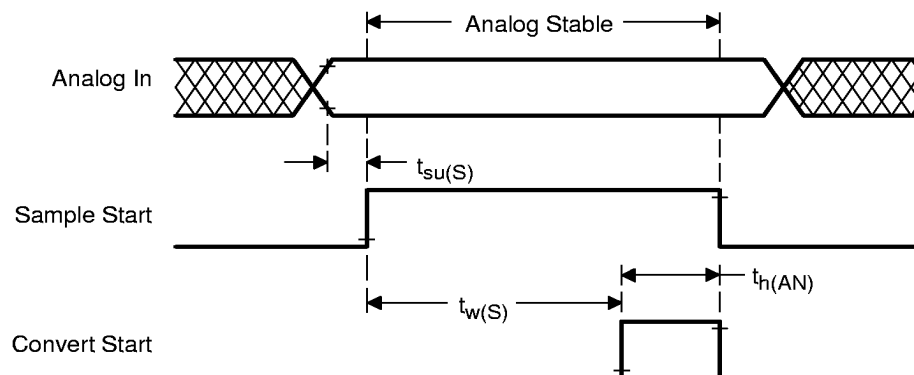
The ADC2 module allows complete freedom in design of the sources for the analog inputs. The period of the sample time is user-defined so that high-impedance sources can be accommodated without penalty to low-impedance sources. The sample period begins when the SAMPLE START bit of the ADC2 control register (ADCTL.6) is set to 1. The end of the signal sample period occurs when the conversion bit (CONVERT START, ADCTL.7) is set to 1. After a hold time, the converter resets the SAMPLE START and CONVERT START bits, signaling that a conversion has started and the analog signal can be removed.

Table 18–85. Analog Timing Requirements

| Parameter | Min | Max | Unit |
|--|---------|-----|------------------------------|
| $t_{su(S)}$ Setup time, analog input to sample command | 0 | | ns |
| $t_{h(AN)}$ Hold time, analog input from start of conversion | $18t_C$ | | ns |
| $t_w(S)$ Pulse duration, sample time per kilohm of source impedance (see Note) | 1 | | $\mu\text{s}/\text{k}\Omega$ |

Note: The value given is valid for a signal with a source impedance $> 1 \text{ k}\Omega$. If the source impedance is $< 1 \text{ k}\Omega$, use a minimum sampling time of $1 \mu\text{s}$.

Figure 18–55. Analog Timing



18.25 Analog-to-Digital Converter 3 (ADC3) Module Specifications

This section contains specifications for the TMS370Cx9x device category, which has the analog-to-digital converter 3 (ADC3) module.

The ADC3 module has a separate power bus for its analog circuitry. These pins are referred to as V_{CC3} and V_{SS3} . The purpose is to enhance ADC3 performance by preventing digital switching noise of the logic circuitry that may be present on V_{SS} and V_{CC} from coupling into the ADC3 analog stage. All ADC3 specifications are given with respect to V_{SS3} unless otherwise noted.

Resolution 8-bits (256 values)
 Monotonic Yes
 Output conversion code 00h to FFh
 (00h for $V_I \leq V_{SS3}$; FFh for $V_I \leq V_{ref}$)
 Conversion time (excluding sample time) $164 t_c$
 (where t_c = system clock cycle time)

Table 18–86. Recommended Operating Conditions

| Parameter | | Min | Nom | Max | Unit |
|-----------|-------------------------------------|----------------|-----------|-----------------|------|
| V_{CC3} | Analog supply voltage | 4.5 | 5 | 5.5 | V |
| | | $V_{CC} - 0.3$ | | $V_{CC} + 0.3$ | V |
| V_{SS3} | Analog input ground | $V_{SS} - 0.3$ | | $V_{SS} + 0.3$ | V |
| V_{ref} | Non- V_{CC3} reference (see Note) | 2.5 | V_{CC3} | $V_{CC3} + 0.1$ | V |
| | Analog input for conversion | V_{SS3} | | V_{ref} | V |

Note: V_{ref} must be stable, within $\pm 1/2$ LSB of the required resolution during the entire conversion time.



Table 18–87. ADC3 Electrical Characteristics Over Recommended Operating Free-Air Temperature Range

| Parameter | | Test Conditions | Min | Max | Unit |
|-----------|---|---|-----|-----------|------------------|
| | Absolute accuracy (see Note 1) | $V_{CC3} = 5.5 \text{ V}$, $V_{ref} = 5.1 \text{ V}$ | | ± 1.5 | LSB |
| | Differential/integral linearity error (see Notes 1 and 2) | $V_{CC3} = 5.5 \text{ V}$, $V_{ref} = 5.1 \text{ V}$ | | ± 0.9 | LSB |
| I_{CC3} | Analog supply current | Converting | | 2 | mA |
| | | Nonconverting | | 5 | μA |
| I_I | Input current, AN0–AN14 | $0 \text{ V} \leq V_I \leq 5.5 \text{ V}$ | | 2 | μA |
| I_{ref} | Input charge current | | | 1 | mA |
| Z_{ref} | Source impedance of V_{ref} | $\text{SYSCLK} \leq 3 \text{ MHz}$ | | 24 | $\text{k}\Omega$ |
| | | $3 \text{ MHz} < \text{SYSCLK} \leq 5 \text{ MHz}$ | | 10 | $\text{k}\Omega$ |

- Notes:**
- 1) Absolute resolution = 20 mV. At $V_{ref} = 5 \text{ V}$, this is 1 LSB. As V_{ref} decreases, LSB size decreases; therefore, the absolute accuracy and differential/integral linearity errors in terms of LSBs increase.
 - 2) Excluding quantization error of 1/2 LSB

The ADC3 module allows complete freedom in design of the sources for the analog inputs. The period of the sample time is user-defined so that high-impedance sources can be accommodated without penalty to low-impedance sources. The sample period begins when the SAMPLE START bit of the ADC3 control register (ADCTL.6) is set to 1. The end of the signal sample period occurs when the conversion bit (CONVERT START, ADCTL.7) is set to 1. After a hold time, the converter resets the SAMPLE START and CONVERT START bits, signaling that a conversion has started and the analog signal can be removed.



Table 18–88. Analog Timing Requirements

| Parameter | | Min | Max | Unit |
|-------------|---|----------------|-----|------------------------------|
| $t_{su(S)}$ | Setup time, analog to sample command | 0 | | ns |
| $t_{h(AN)}$ | Hold time, analog input from start of conversion (see Note 2) | $(N+2)t_c$ | | ns |
| $t_{w(C)}$ | Conversion time (see Note 2) | $(10N + 4)t_c$ | | ns |
| $t_{w(S)}$ | Pulse duration, sample time per kilohm of source impedance (see Note 1) | 1 | | $\mu\text{s}/\text{k}\Omega$ |

Notes: 1) The value given is valid for a signal with a source impedance > 1 k Ω . If the source impedance is < 1 k Ω , use a minimum sampling time of 1 μs .

2) N = 16, 8, 4, or 2 upon selected conversion rate.

Figure 18–56. Analog Timing

